- Highest Performance Floating-Point Digital Signal Processor (DSP) TMS320C6701
 - 8.3-, 6.7-, 6-ns Instruction Cycle Time
 - 120-, 150-, 167-MHz Clock Rate
 - Eight 32-Bit Instructions/Cycle
 - 1 GFLOPS
 - TMS320C6201 Fixed-Point DSP Pin-Compatible
- VelociTI™ Advanced Very Long Instruction Word (VLIW) C67x CPU Core
 - Eight Highly Independent Functional Units:
 - Four ALUs (Floating- and Fixed-Point)
 - Two ALUs (Fixed-Point)
 - Two Multipliers (Floating- and Fixed-Point)
 - Load-Store Architecture With 32 32-Bit General-Purpose Registers
 - Instruction Packing Reduces Code Size
 - All Instructions Conditional
- Instruction Set Features
 - Hardware Support for IEEE
 Single-Precision Instructions
 - Hardware Support for IEEE
 Double-Precision Instructions
 - Byte-Addressable (8-, 16-, 32-Bit Data)
 - 8-Bit Overflow Protection
 - Saturation
 - Bit-Field Extract, Set, Clear
 - Bit-Counting
 - Normalization
- 1M-Bit On-Chip SRAM
 - 512K-Bit Internal Program/Cache (16K 32-Bit Instructions)
 - 512K-Bit Dual-Access Internal Data (64K Bytes)
- 32-Bit External Memory Interface (EMIF)
 - Glueless Interface to Synchronous Memories: SDRAM and SBSRAM
 - Glueless Interface to Asynchronous Memories: SRAM and EPROM
 - 52M-Byte Addressable External Memory Space
- Four-Channel Bootloading Direct-Memory-Access (DMA) Controller With an Auxiliary Channel

GJC (352-PIN BGA) PACKAGE (BOTTOM VIEW)

0000

- 16-Bit Host-Port Interface (HPI)
 - Access to Entire Memory Map
- Two Multichannel Buffered Serial Ports (McBSPs)
 - Direct Interface to T1/E1, MVIP, SCSA Framers
 - ST-Bus-Switching Compatible
 - Up to 256 Channels Each
 - AC97-Compatible
 - Serial-Peripheral-Interface (SPI)
 Compatible (Motorola™)
- Two 32-Bit General-Purpose Timers
- Flexible Phase-Locked-Loop (PLL) Clock Generator
- IEEE-1149.1 (JTAG[†]) Boundary-Scan-Compatible
- 352-Pin Ball Grid Array (BGA) Package (GJC Suffix)
- 0.18-μm/5-Level Metal Process
 - CMOS Technology
- 3.3-V I/Os, 1.8-V Internal (120-, 150-MHz)
- 3.3-V I/Os, 1.9-V Internal (167-MHz Only)



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VelociTI is a trademark of Texas Instruments.

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[†] IEEE Standard 1149.1-1990 Standard-Test-Access Port and Boundary Scan Architecture.



TMS320C6701 FLOATING-POINT DIGITAL SIGNAL PROCESSOR

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description

The TMS320C67x DSPs are the floating-point DSP family in the TMS320C6000™ DSP platform. The TMS320C6701 (C6701) device is based on the high-performance, advanced VelociTI very-long-instruction-word (VLIW) architecture developed by Texas Instruments (TI), making this DSP an excellent choice for multichannel and multifunction applications. With performance of up to 1 giga floating-point operations per second (GFLOPS) at a clock rate of 167 MHz, the C6701 offers cost-effective solutions to high-performance DSP programming challenges. The C6701 DSP possesses the operational flexibility of high-speed controllers and the numerical capability of array processors. This processor has 32 general-purpose registers of 32-bit word length and eight highly independent functional units. The eight functional units provide four floating-/fixed-point ALUs, two fixed-point ALUs, and two floating-/fixed-point multipliers. The C6701 can produce two multiply-accumulates (MACs) per cycle for a total of 334 million MACs per second (MMACS). The C6701 DSP also has application-specific hardware logic, on-chip memory, and additional on-chip peripherals.

The C6701 includes a large bank of on-chip memory and has a powerful and diverse set of peripherals. Program memory consists of a 64K-byte block that is user-configurable as cache or memory-mapped program space. Data memory consists of two 32K-byte blocks of RAM. The peripheral set includes two multichannel buffered serial ports (McBSPs), two general-purpose timers, a host-port interface (HPI), and a glueless external memory interface (EMIF) capable of interfacing to SDRAM or SBSRAM and asynchronous peripherals.

The C6701 has a complete set of development tools which includes: a new C compiler, an assembly optimizer to simplify programming and scheduling, and a Windows™ debugger interface for visibility into source code execution.

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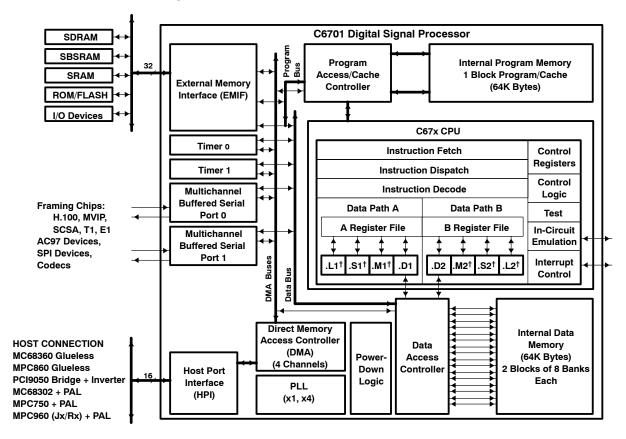
device characteristics

Table 1 provides an overview of the C6701 DSP. The table shows significant features of each device, including the capacity of on-chip RAM, the peripherals, the execution time, and the package type with pin count, etc.

Table 1. Characteristics of the C6701 Processors

HARDW	ARE FEATURES	C6701
	EMIF	1
	DMA	4-Channel
Peripherals	Host-Port Interface (HPI)	1
	McBSPs	2
	32-Bit Timers	2
Internal Dramma Manage	Size (Bytes)	64K
Internal Program Memory	Organization	64K Bytes Cache/Mapped Program
Internal Data Mamon	Size (Bytes)	64K
Internal Data Memory	Organization	2 Blocks: Eight 16-Bit Banks per Block 50/50 Split
Frequency	MHz	120, 150, 167
Cycle Time	ns	6 ns (6701-167); 6.7 ns (6701-150); 8.3 ns (6701-120)
	Co	1.8 (6701-120, -150)
Voltage	Core (V)	1.9 (6701-167 only)
	I/O (V)	3.3
PLL Options	CLKIN frequency multiplier	Bypass (x1), x4
BGA Package	35 × 35 mm	352-pin GJC
Process Technology	μm	0.18 μm
Product Status	Product Preview (PP) Advance Information (AI) Production Data (PD)	PD

functional block and CPU diagram



[†] These functional units execute floating-point instructions.



CPU description

The CPU fetches VelociTI advanced very-long instruction words (VLIW) (256 bits wide) to supply up to eight 32-bit instructions to the eight functional units during every clock cycle. The VelociTI VLIW architecture features controls by which all eight units do not have to be supplied with instructions if they are not ready to execute. The first bit of every 32-bit instruction determines if the next instruction belongs to the same execute packet as the previous instruction, or whether it should be executed in the following clock as a part of the next execute packet. Fetch packets are always 256 bits wide; however, the execute packets can vary in size. The variable-length execute packets are a key memory-saving feature, distinguishing the C67x CPU from other VLIW architectures.

The CPU features two sets of functional units. Each set contains four units and a register file. One set contains functional units .L1, .S1, .M1, and .D1; the other set contains units .D2, .M2, .S2, and .L2. The two register files contain 16 32-bit registers each for the total of 32 general-purpose registers. The two sets of functional units, along with two register files, compose sides A and B of the CPU (see the Functional and CPU Block diagram and Figure 1). The four functional units on each side of the CPU can freely share the 16 registers belonging to that side. Additionally, each side features a single data bus connected to all registers on the other side, by which the two sets of functional units can access data from the register files on opposite sides. While register access by functional units on the same side of the CPU as the register file can service all the units in a single clock cycle, register access using the register file across the CPU supports one read and one write per cycle.

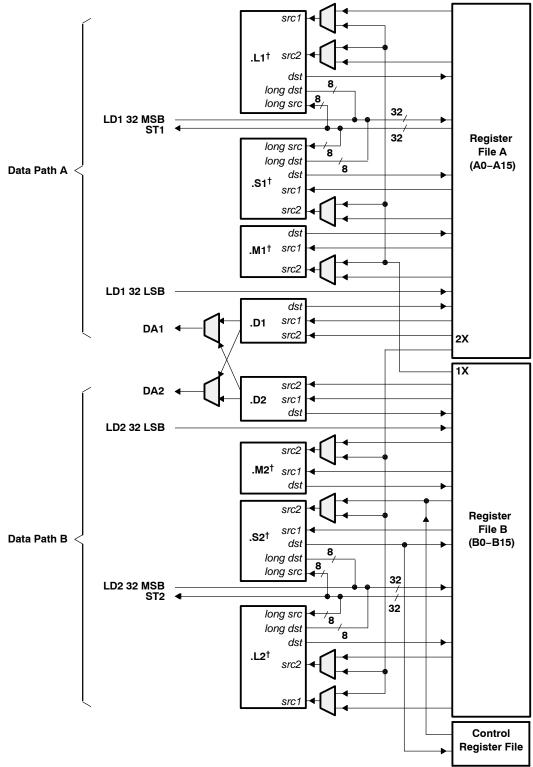
The C67x CPU executes all TMS320C62x[™] DSP fixed-point instructions. In addition to the C62x DSP fixed-point instructions, the six out of eight functional units (.L1, .M1, .D1, .D2, .M2, and .L2) also execute floating-point instructions. The remaining two functional units (.S1 and .S2) also execute the new LDDW instruction which loads 64 bits per CPU side for a total of 128 bits per cycle.

Another key feature of the C67x CPU is the load/store architecture, where all instructions operate on registers (as opposed to data in memory). Two sets of data-addressing units (.D1 and .D2) are responsible for all data transfers between the register files and the memory. The data address driven by the .D units allows data addresses generated from one register file to be used to load or store data to or from the other register file. The C67x CPU supports a variety of indirect-addressing modes using either linear- or circular-addressing modes with 5- or 15-bit offsets. All instructions are conditional, and most can access any one of the 32 registers. Some registers, however, are singled out to support specific addressing or to hold the condition for conditional instructions (if the condition is not automatically "true"). The two .M functional units are dedicated for multiplies. The two .S and .L functional units perform a general set of arithmetic, logical, and branch functions with results available every clock cycle.

The processing flow begins when a 256-bit-wide instruction fetch packet is fetched from a program memory. The 32-bit instructions destined for the individual functional units are "linked" together by "1" bits in the least significant bit (LSB) position of the instructions. The instructions that are "chained" together for simultaneous execution (up to eight in total) compose an execute packet. A "0" in the LSB of an instruction breaks the chain, effectively placing the instructions that follow it in the next execute packet. If an execute packet crosses the fetch-packet boundary (256 bits wide), the assembler places it in the next fetch packet, while the remainder of the current fetch packet is padded with NOP instructions. The number of execute packets within a fetch packet can vary from one to eight. Execute packets are dispatched to their respective functional units at the rate of one per clock cycle and the next 256-bit fetch packet is not fetched until all the execute packets from the current fetch packet have been dispatched. After decoding, the instructions simultaneously drive all active functional units for a maximum execution rate of eight instructions every clock cycle. While most results are stored in 32-bit registers, they can be subsequently moved to memory as bytes or half-words as well. All load and store instructions are byte-, half-word, or word-addressable.

TMS320C62x is a trademark of Texas Instruments

CPU description (continued)



[†] These functional units execute floating-point instructions.

Figure 1. TMS320C67x CPU Data Paths



signal groups description

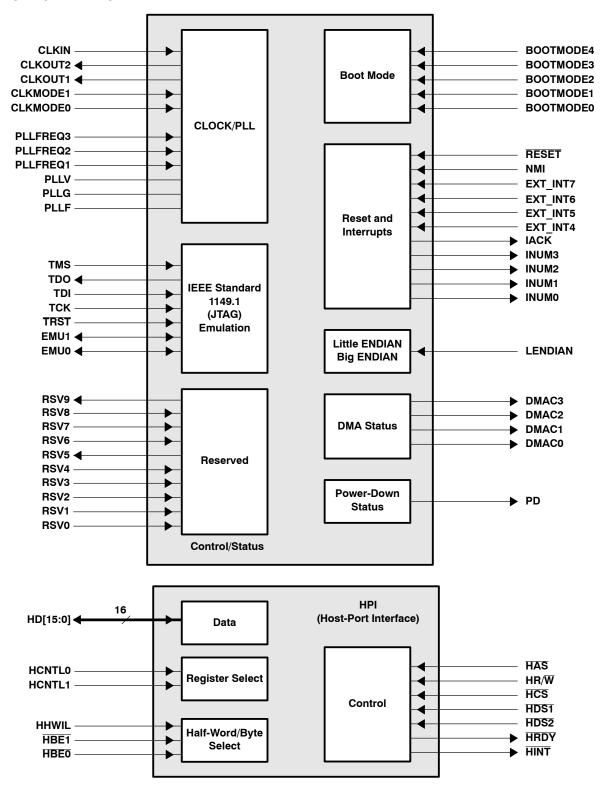


Figure 2. CPU and Peripheral Signals



signal groups description (continued)

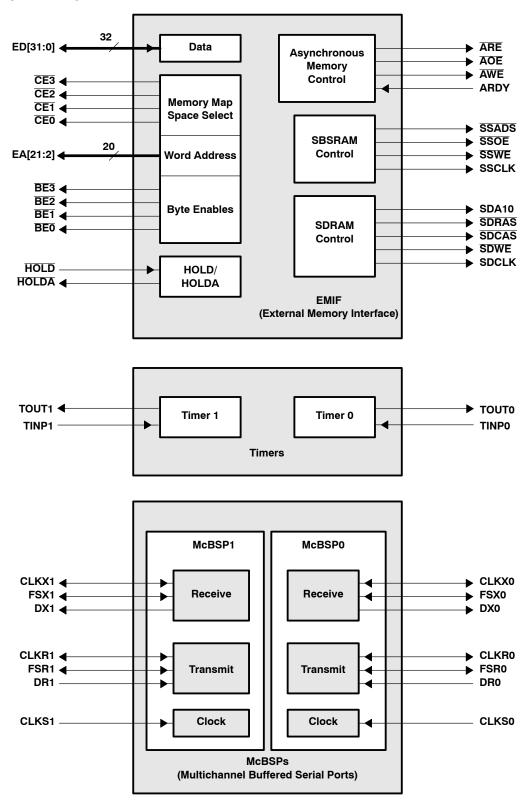


Figure 3. Peripheral Signals



Signal Descriptions

SIGNA	L						
NAME	NO.	TYPE†	DESCRIPTION				
	CLOCK/PLL						
CLKIN	C10	I	Clock Input				
CLKOUT1	AF22	0	Clock output at full device speed				
CLKOUT2	AF20	0	Clock output at half of device speed				
CLKMODE1	C6		Clock mode select				
CLKMODE0	C5	1	Selects whether the output clock frequency = input clock frequency x4 or x1				
PLLFREQ3	A9		DIL frances (0.0 and 1)				
PLLFREQ2	D11	ı	PLL frequency range (3, 2, and 1)				
PLLFREQ1	B10		The target range for CLKOUT1 frequency is determined by the 3-bit value of the PLLFREQ pins.				
PLLV [‡]	D12	Α§	PLL analog V _{CC} connection for the low-pass filter				
PLLG [‡]	C12	Α§	PLL analog GND connection for the low-pass filter				
PLLF	A11	Α§	PLL low-pass filter connection to external components and a bypass capacitor				
			JTAG EMULATION				
TMS	L3	I	JTAG test-port mode select (features an internal pullup)				
TDO	W2	O/Z	JTAG test-port data out				
TDI	R4	I	JTAG test-port data in (features an internal pullup)				
TCK	R3	I	JTAG test-port clock				
TRST	T1	I	JTAG test-port reset (features an internal pulldown)				
EMU1	Y1	I/O/Z	Emulation pin 1, pullup with a dedicated 20-kΩ resistor [¶]				
EMU0	W3	I/O/Z	Emulation pin 0, pullup with a dedicated 20-kΩ resistor [¶]				
			CONTROL				
RESET	K2	I	Device reset				
NINAL			Nonmaskable interrupt				
NMI	L2	l	☐ Edge-driven (rising edge)				
EXT_INT7	U3						
EXT_INT6	V2	1 .	External interrupts				
EXT_INT5	W1	1	☐ Edge-driven (rising edge)				
EXT_INT4	U4						
IACK	Y2	0	Interrupt acknowledge for all active interrupts serviced by the CPU				
INUM3	AA1						
INUM2	W4		Active interrupt identification number				
INUM1	AA2	0	☐ Valid during IACK for all active interrupts (not just external) ☐ Encoding order follows the interrupt-service fetch-packet ordering				
INUM0	AB1		Encoding order follows the interrupt-service fetch-packet ordering				
LENDIAN	НЗ	I	If high, LENDIAN selects little-endian byte/half-word addressing order within a word If low, LENDIAN selects big-endian addressing				
PD	D3	0	Power-down mode 3 (active if high)				

[†] I = Input, O = Output, Z = High Impedance, S = Supply Voltage, GND = Ground



[‡] PLLV and PLLG are not part of external voltage supply or ground. See the CLOCK/PLL documentation for information on how to connect these pins.

[§] A = Analog Signal (PLL Filter)

[¶] For emulation and normal operation, pull up EMU1 and EMU0 with a dedicated 20-k Ω resistor. For boundary scan, pull down EMU1 and EMU0 with a dedicated 20-k Ω resistor.

SIGNAL			Cignal Decemptions (Commucal)			
NAME	NO.	TYPE†	DESCRIPTION			
	HOST-PORT INTERFACE (HPI)					
HINT	H26	0	Host interrupt (from DSP to host)			
HCNTL1	F23	I	Host control - selects between control, address, or data registers			
HCNTL0	D25	I	Host control - selects between control, address, or data registers			
HHWIL	C26	I	Host half-word select – first or second half-word (not necessarily high or low order)			
HBE1	E23	I	Host byte select within word or half-word			
HBE0	D24	I	Host byte select within word or half-word			
HR/W	C23	I	Host read or write select			
HD15	B13					
HD14	B14					
HD13	C14					
HD12	B15					
HD11	D15					
HD10	B16					
HD9	A17					
HD8	B17					
HD7	D16	I/O/Z	Host-port data (used for transfer of data, address, and control)			
HD6	B18					
HD5	A19					
HD4	C18					
HD3	B19					
HD2	C19					
HD1	B20					
HD0	B21					
HAS	C22	I	Host address strobe			
HCS	B23	I	Host chip select			
HDS1	D22	I	Host data strobe 1			
HDS2	A24	I	Host data strobe 2			
HRDY	J24	0	Host ready (from DSP to host)			
	BOOT MODE					
BOOTMODE4	D8					
BOOTMODE3	B4					
BOOTMODE2	A3	ı	Boot mode			
BOOTMODE1	D5					
BOOTMODE0	C4					

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SIGNA	۱L		
NAME	NO.	TYPE†	DESCRIPTION
		E	MIF - CONTROL SIGNALS COMMON TO ALL TYPES OF MEMORY
CE3	AE22	O/Z	
CE2	AD26	O/Z	Memory space enables
CE1	AB24	O/Z	☐ Enabled by bits 24 and 25 of the word address
CE0	AC26	O/Z	Only one asserted during any external data access
BE3	AB25	O/Z	Byte-enable control
BE2	AA24	O/Z	Decoded from the two lowest bits of the internal address
BE1	Y23	O/Z	Byte-write enables for most types of memory
BE0	AA26	O/Z	Can be directly connected to SDRAM read and write mask signal (SDQM)
			EMIF - ADDRESS
EA21	J26		
EA20	K25		
EA19	L24		
EA18	K26		
EA17	M26		
EA16	M25		
EA15	P25		
EA14	P24		
EA13	R25		
EA12	T26	0/7	C.dovost address (v.and address)
EA11	R23	O/Z	External address (word address)
EA10	U26		
EA9	U25		
EA8	T23		
EA7	V26		
EA6	V25		
EA5	W26		
EA4	V24		
EA3	W25		
EA2	Y26		

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SIGNA	SIGNAL				
NAME	NO.	TYPE†	DESCRIPTION		
			EMIF - DATA		
ED31	AB2				
ED30	AC1				
ED29	AA4				
ED28	AD1				
ED27	AC3				
ED26	AD4				
ED25	AF3				
ED24	AE4				
ED23	AD5				
ED22	AF4				
ED21	AE5				
ED20	AD6				
ED19	AE6				
ED18	AD7				
ED17	AC8				
ED16	AF7	1/0/7	E to well date		
ED15	AD9	I/O/Z	External data		
ED14	AD10				
ED13	AF9				
ED12	AC11				
ED11	AE10				
ED10	AE11				
ED9	AF11				
ED8	AE14				
ED7	AF15				
ED6	AE15				
ED5	AF16]			
ED4	AC15				
ED3	AE17				
ED2	AF18				
ED1	AF19				
ED0	AC17				
		1	EMIF - ASYNCHRONOUS MEMORY CONTROL		
ARE	Y24	O/Z	Asynchronous memory read enable		
AOE	AC24	O/Z	Asynchronous memory output enable		
AWE	AD23	O/Z	Asynchronous memory write enable		
ARDY	W23	I	Asynchronous memory ready input		

[†] I = Input, O = Output, Z = High Impedance, S = Supply Voltage, GND = Ground



SIGNA	AL.				
NAME	NO.	TYPE [†]	DESCRIPTION		
		•	EMIF - SYNCHRONOUS BURST SRAM CONTROL		
SSADS	AC20	O/Z	SBSRAM address strobe		
SSOE	AF21	O/Z	SBSRAM output enable		
SSWE	AD19	O/Z	SBSRAM write enable		
SSCLK	AD17	0	SBSRAM clock		
			EMIF - SYNCHRONOUS DRAM CONTROL		
SDA10	AD21	O/Z	SDRAM address 10 (separate for deactivate command)		
SDRAS	AF24	O/Z	SDRAM row-address strobe		
SDCAS	AD22	O/Z	SDRAM column-address strobe		
SDWE	AF23	O/Z	SDRAM write enable		
SDCLK	AE20	0	SDRAM clock		
			EMIF - BUS ARBITRATION		
HOLD	AA25	I	Hold request from the host		
HOLDA	A7	0	Hold-request-acknowledge to the host		
			TIMERS		
TOUT1	H24	0	Timer 1 or general-purpose output		
TINP1	K24	I	Timer 1 or general-purpose input		
TOUT0	M4	0	Timer 0 or general-purpose output		
TINP0	K4	I	Timer 0 or general-purpose input		
			DMA ACTION COMPLETE		
DMAC3	D2				
DMAC2	F4	0	DMA astica consulate		
DMAC1	D1		DMA action complete		
DMAC0	E2				
MULTICHANNEL BUFFERED SERIAL PORT 1 (McBSP1)					
CLKS1	E25	I	External clock source (as opposed to internal)		
CLKR1	H23	I/O/Z	Receive clock		
CLKX1	F26	I/O/Z	Transmit clock		
DR1	D26	I	Receive data		
DX1	G23	O/Z	Transmit data		
FSR1	E26	I/O/Z	Receive frame sync		
FSX1	F25	I/O/Z	Transmit frame sync		

[†] I = Input, O = Output, Z = High Impedance, S = Supply Voltage, GND = Ground

SIGNA	\L		oighti bescriptions (continued)			
NAME	NO.	TYPE†	DESCRIPTION			
	MULTICHANNEL BUFFERED SERIAL PORT 0 (McBSP0)					
CLKS0	L4	ı	External clock source (as opposed to internal)			
CLKR0	M2	I/O/Z	Receive clock			
CLKX0	L1	I/O/Z	Transmit clock			
DR0	J1	ı	Receive data			
DX0	R1	O/Z	Transmit data			
FSR0	P4	I/O/Z	Receive frame sync			
FSX0	P3	I/O/Z	Transmit frame sync			
			RESERVED FOR TEST			
RSV0	T2	I	Reserved for testing, pullup with a dedicated 20-k Ω resistor			
RSV1	G2	I	Reserved for testing, pullup with a dedicated 20-k Ω resistor			
RSV2	C11	I	Reserved for testing, pullup with a dedicated 20-k Ω resistor			
RSV3	B9	I	Reserved for testing, pullup with a dedicated 20-k Ω resistor			
RSV4	A6	I	Reserved for testing, $\textit{pulldown}$ with a dedicated 20-k Ω resistor			
RSV5	C8	0	Reserved (leave unconnected, do not connect to power or ground)			
RSV6	C21	I	Reserved for testing, pullup with a dedicated 20-k Ω resistor			
RSV7	B22	I	Reserved for testing, pullup with a dedicated 20-k Ω resistor			
RSV8	A23	I	Reserved for testing, pullup with a dedicated 20-k Ω resistor			
RSV9	E4	0	Reserved (leave unconnected, <i>do not</i> connect to power or ground)			
			SUPPLY VOLTAGE PINS			
	A10					
	A15					
	A18					
	A21					
	A22					
	B7					
	C1					
	D17					
	F3					
	G24					
DV_DD	G25	S	3.3-V supply voltage			
	H25					
	J25					
	L25					
	M3					
	N3					
	N23					
	R26					
	T24					
	U24					
	W24					

[†] I = Input, O = Output, Z = High Impedance, S = Supply Voltage, GND = Ground



SIGNAI	L		
NAME	NO.	TYPE†	DESCRIPTION
			SUPPLY VOLTAGE PINS (CONTINUED)
	Y4		
	AB3		
	AB4		
	AB26		
	AC6		
	AC10		
	AC19		
	AC21		
	AC22		
DV_DD	AC25	S	3.3-V supply voltage
	AD11		
	AD13		
	AD15		
	AD18		
	AE18		
	AE21		
	AF5		
	AF6		
	AF17		
	A5		
	A12		
	A16		
	A20		
	B2 B6		
	B11		
	B12		
	B25		
	C3		1.8-V supply voltage (for 6701-120, -150)
CV _{DD}	C15	S	1.8-V supply voltage (for 6701-120, -150) 1.9-V supply voltage (for 6701-167 only)
	C20		
	C24		
	D4		
	D6		
	D7		
	D9		
	D14		
	D18		
	D20		

[†] I = Input, O = Output, Z = High Impedance, S = Supply Voltage, GND = Ground

NAME	SIGNA	 L		
E1 F1 H4 J4 J23 K1 K23 M1 M24 N4 N25 P2 P23 T3 T3 T4 U1 V23 AC4 AC9 AC12 AC13 AC18 AC23 AD3 AD8 AD14 AD24	NAME	NO.	TYPET	DESCRIPTION
E1 F1 H4 J4 J23 K1 K23 M1 M24 N4 N25 P2 P23 T3 T4 U1 V4 V23 AC4 AC9 AC12 AC13 AC18 AC23 AD3 AD8 AD14 AD24				SUPPLY VOLTAGE PINS (CONTINUED)
AE2 AE8 AE12 AE25	CV _{DD}	E1 F1 H4 J4 J23 K1 K23 M1 M24 N4 N25 P2 P23 T3 T4 U1 V4 V23 AC4 AC9 AC12 AC13 AC18 AC23 AD3 AD8 AD14 AD24 AE2 AE8 AE12	S	1.8-V supply voltage (for 6701-120, -150)

[†] I = Input, O = Output, Z = High Impedance, S = Supply Voltage, GND = Ground

SIGNAL			olgilai besoriptions (continued)				
NAME	NO.	TYPE†	DESCRIPTION				
	GROUND PINS						
	A1						
	A2						
	A4						
	A13						
	A14						
	A25						
	A26						
	B1						
	B3						
	B5						
	B24						
	B26						
	C2						
	C7						
	C13						
	C16	ļ					
	C17						
	C25						
	D13						
V _{SS}	D19	GND	Ground pins				
	E3						
	E24						
	F2						
	F24	ļ					
	G3						
	G4						
	G26	-					
	J3 L23	1					
	L23	1					
	M23	•					
	N1	1					
	N2	1					
	N24	1					
	N26	1					
	P1	1					
	P26	1					
	R24	1					
	T25	1					

T25 | T25 | T25 | T25 | T25 | T35 |

SIGNAL			olgilai becomplione (continuea)				
NAME	NO.	TYPE†	DESCRIPTION				
	GROUND PINS (CONTINUED)						
	U2						
	U23						
	V1						
	V3						
	Y3						
	Y25						
	AA3						
	AA23						
	AB23						
	AC2						
	AC5						
	AC7						
	AC14						
	AC16						
	AD2						
	AD12	GND					
	AD16						
	AD20						
V_{SS}	AD25		Ground pins				
	AE1						
	AE3						
	AE7						
	AE9						
	AE13						
	AE16						
	AE19						
	AE23						
	AE24						
	AE26						
	AF1						
	AF2						
	AF8						
	AF10	_					
	AF13						
	AF14						
	AF25						
	AF26						

[†] I = Input, O = Output, Z = High Impedance, S = Supply Voltage, GND = Ground



TMS320C6701 FLOATING-POINT DIGITAL SIGNAL PROCESSOR

SPRS067F - MAY 1998 - REVISED MARCH 2004

SIGNA	\L		
NAME	NO.	TYPE†	DESCRIPTION
			REMAINING UNCONNECTED PINS
	A8		
	B8]	
	C9]	
	D10	1	
	D21	1	
NC	G1]	Unconnected pins
	H1]	
	H2]	
	J2		
	K3		
	R2		

[†] I = Input, O = Output, Z = High Impedance, S = Supply Voltage, GND = Ground

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development support

TI offers an extensive line of development tools for the TMS320C6000 DSP platform, including tools to evaluate the performance of the processors, generate code, develop algorithm implementations, and fully integrate and debug software and hardware modules.

The following products support development of C6000[™] DSP-based applications:

Software Development Tools:

Code Composer Studio™ Integrated Development Environment (IDE): including Editor C/C++/Assembly Code Generation, and Debug plus additional development tools Scalable, Real-Time Foundation Software (DSP BIOS), which provides the basic run-time target software needed to support any DSP application.

Hardware Development Tools:

Extended Development System (XDS™) Emulator (supports C6000™ DSP multiprocessor system debug) EVM (Evaluation Module)

The *TMS320 DSP Development Support Reference Guide* (SPRU011) contains information about development-support products for all TMS320™ DSP family member devices, including documentation. See this document for further information on TMS320™ DSP documentation or any TMS320™ DSP support products from Texas Instruments. An additional document, the *TMS320 Third-Party Support Reference Guide* (SPRU052), contains information about TMS320™ DSP-related products from other companies in the industry. To receive TMS320™ DSP literature, contact the Literature Response Center at 800/477-8924.

For a complete listing of development-support tools for the TMS320C6000 DSP platform, visit the Texas Instruments web site on the Worldwide Web at http://www.ti.com uniform resource locator (URL) and under "Development Tools", select "Digital Signal Processors". For information on pricing and availability, contact the nearest TI field sales office or authorized distributor.

Code Composer Studio, XDS, and TMS320 are trademarks of Texas Instruments.



device and development-support tool nomenclature

To designate the stages in the product-development cycle, TI assigns prefixes to the part numbers of all TMS320 DSP devices and support tools. Each TMS320 DSP family member has one of three prefixes: TMX, TMP, or TMS. Texas Instruments recommends two of three possible prefix designators for support tools: TMDX and TMDS. These prefixes represent evolutionary stages of product development from engineering prototypes (TMX/TMDX) through fully qualified production devices/tools (TMS/TMDS).

Device development evolutionary flow:

TMX Experimental device that is not necessarily representative of the final device's electrical

specifications

TMP Final silicon die that conforms to the device's electrical specifications but has not completed

quality and reliability verification

TMS Fully qualified production device

Support tool development evolutionary flow:

TMDX Development-support product that has not yet completed Texas Instruments internal qualification

testing.

TMDS Fully qualified development-support product

TMX and TMP devices and TMDX development-support tools are shipped against the following disclaimer:

"Developmental product is intended for internal evaluation purposes."

TMS devices and TMDS development-support tools have been characterized fully, and the quality and reliability of the device have been demonstrated fully. TI's standard warranty applies.

Predictions show that prototype devices (TMX or TMP) have a greater failure rate than the standard production devices. Texas Instruments recommends that these devices not be used in any production system because their expected end-use failure rate still is undefined. Only qualified production devices are to be used.

TI device nomenclature also includes a suffix with the device family name. This suffix indicates the package type (for example, GJC), the temperature range (for example, blank is the default commercial temperature range), and the device speed range in megahertz (for example, -167 is 167 MHz). Table 2 identifies the available TMS320C6701 devices by their associated orderable part numbers (P/Ns) and gives device-specific ordering information (for example, device speeds, core and I/O supply voltage values, and device operating temperature ranges). Figure 4 provides a legend for reading the complete device name for any TMS320™ DSP family member.

Table 2. TMS320C6701 Device P/Ns and Ordering Information

DEVICE ORDERABLE P/N	DEVICE SPEED	CV _{DD} (CORE VOLTAGE)	DV _{DD} (I/O VOLTAGE)	OPERATING CASE TEMPERATURE RANGE
TMSC6701GJC16719V	167 MHz/1 GFLOPS	1.9 V	3.3 V	0°C to 90°C
TMS320C6701GJC150	150 MHz/900 MFLOPS	1.8 V	3.3 V	0°C to 90°C
TMS320C6701GJCA120	120 MHz/720 MFLOPS	1.8 V	3.3 V	–40°C to 105°C



device and development-support tool nomenclature (continued) TMS 320 C 6701 GJC (A) 167 **DEVICE SPEED RANGE** PREFIX -100 MHz 200 MHz TMX = Experimental device 120 MHz 233 MHz TMP= Prototype device 150 MHz 250 MHz TMS = Qualified device 167 MHz 300 MHz SMJ = MIL-PRF-38535 (QML) Commercial processing **DEVICE FAMILY** -320 = TMS320™ DSP family TEMPERATURE RANGE (DEFAULT: 0°C TO 90°C) Blank = 0°C to 90°C, commercial temperature = -40°C to 105°C, extended temperature PACKAGE TYPE† Plastic DIP TECHNOLOGY-Ceramic DIP JD Ceramic DIP side-brazed **CMOS** = GB Ceramic PGA **CMOS EPROM** Ceramic CC **CMOS Flash EEPROM** Plastic leaded CC Ceramic leadless CC 100-pin plastic EIAJ QFP PQ 132-pin plastic bumpered QFP 100-pin plastic TQFP PBK = 128-pin plastic TQFP PGE = 144-pin plastic TQFP 256-pin plastic BGA 144-pin plastic BGA GFN = GGU = 144-pin plastic BGA 352-pin plastic BGA 352-pin plastic BGA 352-pin plastic BGA 384-pin plastic BGA 340-pin plastic BGA 288-pin plastic MicroStar BGA™ GGP = GJC = GJL = GLS = GLW = GHK = **DEVICE** '1x DSP: 10 16 14 17 15 '2x DSP: 25 26 '2xx DSP: 203 206 240 204 209 '3x DSP: 30 31 32 '4x DSP: '5x DSP: 50 51 56 52 57 [†] DIP = Dual-In-Line Package '54x DSP 541 545 PGA = Pin Grid Array 546 542 CC Chip Carrier = 543 548 QFP = Quad Flat Package 6x DSP: TQFP = Thin Quad Flat Package 6201 6205 6202 6211 BGA = Ball Grid Array 6202B 6701 6203

Figure 4. TMS320 DSP Device Nomenclature (Including TMS320C6701)

6711

6204

MicroStar BGA is a trademark of Texas Instruments.



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documentation support

Extensive documentation supports all TMS320 DSP family generations of devices from product announcement through applications development. The types of documentation available include: data sheets, such as this document, with design specifications; complete user's reference guides for all devices; technical briefs; development-support tools; and hardware and software applications. The following is a brief, descriptive list of support documentation specific to the C6x devices:

The *TMS320C6000 CPU and Instruction Set Reference Guide* (literature number SPRU189) describes the C6000 DSP CPU architecture, instruction set, pipeline, and associated interrupts.

The *TMS320C6000 DSP Peripherals Overview Reference Guide* (literature number SPRU190) briefly describes the functionality of the peripherals available on C6x devices, such as the external memory interface (EMIF), host-port interface (HPI), multichannel buffered serial ports (McBSPs), direct-memory-access (DMA), enhanced direct-memory-access (EDMA) controller, expansion bus (XB), clocking and phase-locked loop (PLL); and power-down modes.

The *TMS320C6000 Technical Brief* (literature number SPRU197) gives an introduction to the C62x/C67x devices, associated development tools, and third-party support.

The tools support documentation is electronically available within the Code Composer Studio™ Integrated Development Environment (IDE). For a complete listing of C6000 DSP latest documentation, visit the Texas Instruments web site on the Worldwide Web at http://www.ti.com uniform resource locator (URL).

clock PLL

All of the internal C67x clocks are generated from a single source through the CLKIN pin. This source clock either drives the PLL, which multiplies the source clock in frequency to generate the internal CPU clock, or bypasses the PLL to become the internal CPU clock.

To use the PLL to generate the CPU clock, the external PLL filter circuit must be properly designed. Table 3, Table 4, and Figure 5 show the external PLL circuitry for either x1 (PLL bypass) or x4 PLL multiply modes. Table 3 and Figure 6 show the external PLL circuitry for a system with ONLY x1 (PLL bypass) mode.

To minimize the clock jitter, a single clean power supply should power both the C67x device and the external clock oscillator circuit. Noise coupling into PLLF directly impacts PLL clock jitter. The minimum CLKIN rise and fall times should also be observed. For the input clock timing requirements, see the *input and output clocks* electricals section.

Table 3. CLKOUT1 Frequency Ranges[†]

PLLFREQ3 (A9)	PLLFREQ2 (D11)	PLLFREQ1 (B10)	CLKOUT1 FREQUENCY RANGE (MHZ)
0	0	0	50–140
0	0	1	65–167
0	1	0	130–167

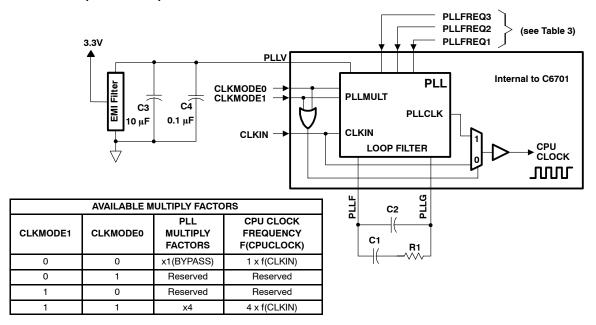
[†] Due to overlap of frequency ranges when choosing the PLLFREQ, more than one frequency range can contain the CLKOUT1 frequency. Choose the lowest frequency range that includes the desired frequency. For example, for CLKOUT1 = 133 MHz, choose PLLFREQ value of 000b. For CLKOUT1 = 167 MHz, choose PLLFREQ value of 001b. PLLFREQ values other than 000b, 001b, and 010b are reserved.

Table 4. C6701 PLL Component Selection Table

CLKMODE	CLKIN RANGE (MHz)	CPU CLOCK FREQUENCY (CLKOUT1) RANGE (MHz)	CLKOUT2 RANGE (MHz)	R1 (Ω)	C1 (nF)	C2 (pF)	TYPICAL LOCK TIME (μs) [‡]
x4	12.5-41.7	50-167	25-83.5	60.4	27	560	75

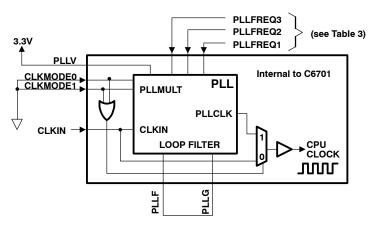
[‡] Under some operating conditions, the maximum PLL lock time may vary as much as 150% from the specified typical value. For example, if the typical lock time is specified as 100 μs, the maximum value may be as long as 250 μs.

clock PLL (continued)



- NOTES: A. Keep the lead length and the number of vias between the PLLF pin, the PLLG pin, and R1, C1, and C2 to a minimum. In addition, place all PLL external components (R1, C1, C2, C3, C4, and the EMI Filter) as close to the C6000™ DSP device as possible. For the best performance, TI recommends that all the PLL external components be on a single side of the board without jumpers, switches, or components other than the ones shown.
 - B. For reduced PLL jitter, maximize the spacing between switching signals and the PLL external components (R1, C1, C2, C3, C4, and the EMI Filter).
 - C. The 3.3-V supply for the EMI filter must be from the same 3.3-V power plane supplying the I/O voltage, DV_{DD} .
 - D. EMI filter manufacturer: TDK part number ACF451832-333, 223, 153, 103. Panasonic part number EXCCET103U.

Figure 5. External PLL Circuitry for Either PLL x4 Mode or x1 (Bypass) Mode



- NOTES: A. For a system with ONLY PLL x1 (bypass) mode, short the PLLF terminal to the PLLG terminal.
 - B. The 3.3-V supply for the EMI filter must be from the same 3.3-V power plane supplying the I/O voltage, DV_{DD} .

Figure 6. External PLL Circuitry for x1 (Bypass) Mode Only



power-down mode logic

Figure 7 shows the power-down mode logic on the C6701.

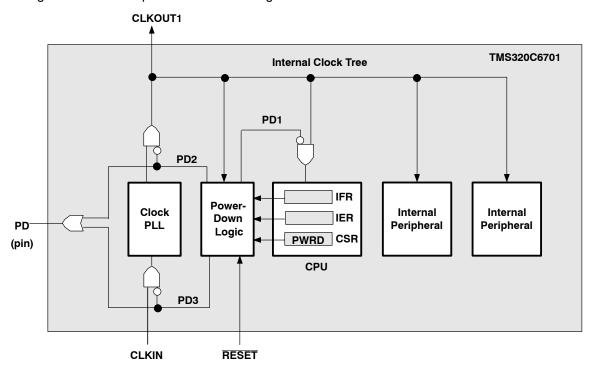


Figure 7. Power-Down Mode Logic[†]

triggering, wake-up, and effects

The power-down modes and their wake-up methods are programmed by setting the PWRD field (bits 15–10) of the control status register (CSR). The PWRD field of the CSR is shown in Figure 8 and described in Table 5. When writing to the CSR, all bits of the PWRD field should be set at the same time. Logic 0 should be used when "writing" to the reserved bit (bit 15) of the PWRD field. The CSR is discussed in detail in the *TMS320C6000 CPU and Instruction Set Reference Guide* (literature number SPRU189).



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31							16
15	14	13	12	11	10	9	8
Reserved	Enable or Non-Enabled Interrupt Wake	Enabled Interrupt Wake	PD3	PD2	PD1		
R/W-0	R/W-0	R/W-0	R/W-0	R/W-0	R/W-0		
7							0

Legend: R/W-x = Read/write reset value

NOTE: The shadowed bits are not part of the power-down logic discussion and therefore are not covered here. For information on these other bit fields in the CSR register, see the *TMS320C6000 CPU and Instruction Set Reference Guide* (literature number SPRU189).

Figure 8. PWRD Field of the CSR Register

Power-down mode PD1 takes effect eight to nine clock cycles after the instruction that sets the PWRD bits in the CSR.

If PD1 mode is terminated by a non-enabled interrupt, the program execution returns to the instruction where PD1 took effect. If PD1 mode is terminated by an enabled interrupt, the interrupt service routine will be executed first, then the program execution returns to the instruction where PD1 took effect. The GIE bit in CSR and the NMIE bit in the interrupt enable register (IER) must also be set in order for the interrupt service routine to execute; otherwise, execution returns to the instruction where PD1 took effect upon PD1 mode termination by an enabled interrupt.

PD2 and PD3 modes can only be aborted by device reset. Table 5 summarizes all the power-down modes.



Table 5. Characteristics of the Power-Down Modes

PRWD FIELD (BITS 15-10)	POWER-DOWN MODE	WAKE-UP METHOD	EFFECT ON CHIP'S OPERATION		
000000	No power-down	_	_		
001001	PD1	Wake by an enabled interrupt	CPU halted (except for the interrupt logic) Power-down mode blocks the internal clock inputs at the		
010001	PD1	Wake by an enabled or non-enabled interrupt	boundary of the CPU, preventing most of the CPU's logic from switching. During PD1, DMA transactions can proceed between peripherals and internal memory.		
011010	PD2 [†]	Wake by a device reset	Output clock from PLL is halted, stopping the internal clock structure from switching and resulting in the entire chip being halted. All register and internal RAM contents are preserved. All functional I/O "freeze" in the last state when the PLL clock is turned off.		
011100	PD3 [†]	Wake by a device reset	Input clock to the PLL stops generating clocks. All register and internal RAM contents are preserved. All functional I/O "freeze" in the last state when the PLL clock is turned off. Following reset, the PLL needs time to re-lock, just as it does following power-up. Wake-up from PD3 takes longer than wake-up from PD2 because the PLL needs to be re-locked.		
All others	Reserved	_	_		

[†] When entering PD2 and PD3, all functional I/O remains in the previous state. However, for peripherals which are asynchronous in nature or peripherals with an external clock source, output signals may transition in response to stimulus on the inputs. Under these conditions, peripherals will not operate according to specifications.

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absolute maximum ratings over operating case temperature range (unless otherwise noted)[†]

Supply voltage range, CV _{DD} (see Note	1)	0.3 V to 2.3 V
Supply voltage range, DV _{DD} (see Note	1)	0.3 V to 4 V
Input voltage range	·····	0.3 V to 4 V
Output voltage range		0.3 V to 4 V
Operating case temperature range, T _C	(Default)	0°C to 90°C
	(A Version)	_40°C to 105°C
Storage temperature range, T _{stg}	······	_55°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to VSS.

recommended operating conditions

			MIN	NOM	MAX	UNIT
0)./	6701-120, -1	6701-120, -150	1.71	1.8	1.89	V
CV _{DD}	Supply voltage, Core [‡]	6701-167 only	1.81	1.9	1.99	V
DV_DD	Supply voltage, I/O [‡]		3.14	3.30	3.46	V
V_{SS}	Supply ground		0	0	0	V
V_{IH}	High-level input voltage		2.0			٧
V_{IL}	Low-level input voltage				0.8	٧
I _{OH}	High-level output current				-12	mA
I _{OL}	Low-level output current				12	mA
T _C	Constant and	Default	0		90	°C
	Case temperature	A Version	-40		105	°C

[‡] TI DSP's do not require specific power sequencing between the core supply and the I/O supply. However, systems should be designed to ensure that neither supply is powered up for extended periods of time if the other supply is below the proper operating voltage. Excessive exposure to these conditions can adversely affect the long term reliability of the device. System-level concerns such as bus contention may require supply sequencing to be implemented. In this case, the core supply should be powered up at the same time as, or prior to (and powered down after), the I/O buffers. For additional power supply sequencing information, see the *Power Supply Sequencing Solutions For Dual Supply Voltage DSPs* application report (literature number SLVA073).

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electrical characteristics over recommended ranges of supply voltage and operating case temperature (unless otherwise noted)

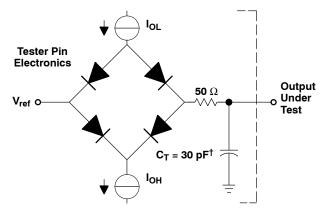
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
V _{OH}	High-level output voltage	$DV_{DD} = MIN,$ $I_{OH} = MAX$	2.4			V	
V_{OL}	Low-level output voltage	$DV_{DD} = MIN,$ $I_{OL} = MAX$			0.6	V	
I _I	Input current [†]	$V_I = V_{SS}$ to DV_{DD}			±10	uA	
loz	Off-state output current	V _O = DV _{DD} or 0 V			±10	uA	
	Constitution and CDLL CDLL according to	CV _{DD} = NOM, CPU clock = 150 MHz	470			^	
I _{DD2V}	Supply current, CPU + CPU memory access‡	CV _{DD} = NOM, CPU clock = 120 MHz		380		mA	
	O sales and a side of	CV _{DD} = NOM, CPU clock = 150 MHz		250		4	
I _{DD2V}	Supply current, peripherals [‡]	CV _{DD} = NOM, CPU clock = 120 MHz		200		mA	
	Construction of the	DV _{DD} = NOM, CPU clock = 150 MHz		85		A	
IDD3V	Supply current, I/O pins [‡]	DV _{DD} = NOM, CPU clock = 120 MHz	70			mA	
Ci	Input capacitance				10	pF	
Co	Output capacitance				10	pF	

[†] TMS and TDI are not included due to internal pullups.

TRST is not included due to internal pulldown.

[‡] Measured with average activity (50% high / 50% low power). For more detailed information on CPU/peripheral/I/O activity, see the *TMS320C6000 Power Consumption Summary* application report (literature number SPRA486).

PARAMETER MEASUREMENT INFORMATION



 $^{^\}dagger$ Typical distributed load circuit capacitance.

signal-transition levels

All input and output timing parameters are referenced to 1.5 V for both "0" and "1" logic levels.

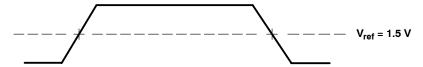


Figure 9. Input and Output Voltage Reference Levels for ac Timing Measurements

INPUT AND OUTPUT CLOCKS

timing requirements for CLKIN (C6701-150, -167 devices only)^{†‡} (see Figure 10)

				C670	1-150			C670	1-167		
NO.			CLKMODE = x4		CLKMODE = x1		CLKMODE = x4		CLKMODE = x1		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
1	t _{c(CLKIN)}	Cycle time, CLKIN	26.7		6.7		24		6		ns
2	t _{w(CLKINH)}	Pulse duration, CLKIN high	0.4C		0.45C		0.4C		0.45C		ns
3	t _{w(CLKINL)}	Pulse duration, CLKIN low	0.4C		0.45C		0.4C		0.45C		ns
4	t _{t(CLKIN)}	Transition time, CLKIN		5		0.6		5		0.6	ns

 $^{^{\}dagger}$ The reference points for the rise and fall transitions are measured at 20% and 80%, respectively, of V_{IH}.

timing requirements for CLKIN (C6701-120 device only)^{†‡} (see Figure 10)

				C670	1-120		
NO.				CLKMODE = x4		CLKMODE = x1	
			MIN	MAX	MIN	MAX	
1	t _{c(CLKIN)}	Cycle time, CLKIN	33.3		8.3		ns
2	t _{w(CLKINH)}	Pulse duration, CLKIN high	0.4C		0.45C		ns
3	t _{w(CLKINL)}	Pulse duration, CLKIN low	0.4C		0.45C		ns
4	t _{t(CLKIN)}	Transition time, CLKIN		5		0.6	ns

 $^{^{\}dagger}$ The reference points for the rise and fall transitions are measured at 20% and 80%, respectively, of V_{IH}.

 $^{^{\}ddagger}$ C = CLKIN cycle time in ns. For example, when CLKIN frequency is 10 MHz, use C = 100 ns.

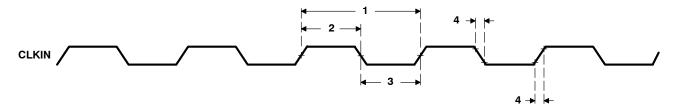


Figure 10. CLKIN Timings

 $^{^{\}ddagger}$ C = CLKIN cycle time in ns. For example, when CLKIN frequency is 10 MHz, use C = 100 ns.

INPUT AND OUTPUT CLOCKS (CONTINUED)

switching characteristics for CLKOUT1^{†‡} (see Figure 11)

NO.	PARAMETER			C6701-120 C6701-150 C6701-167					
			CLKMO	DE = X4	CLKMODE = X1				
			MIN	MAX	MIN	MAX			
1	t _{c(CKO1)}	Cycle time, CLKOUT1	P – 0.7	P + 0.7	P – 0.7	P + 0.7	ns		
2	t _{w(CKO1H)}	Pulse duration, CLKOUT1 high	(P/2) - 0.5	(P/2) + 0.5	PH – 0.5	PH + 0.5	ns		
3	t _{w(CKO1L)}	Pulse duration, CLKOUT1 low	(P/2) - 0.5	(P/2) + 0.5	PL - 0.5	PL + 0.5	ns		
4	t _{t(CKO1)}	Transition time, CLKOUT1		0.6		0.6	ns		

[†] P = 1/CPU clock frequency in nanoseconds (ns).

[‡] PH is the high period of CLKIN in ns and PL is the low period of CLKIN in ns.

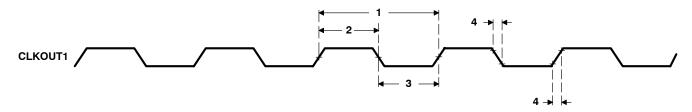


Figure 11. CLKOUT1 Timings

switching characteristics for CLKOUT2§ (see Figure 12)

NO.	PARAMETER		C6701-120 C6701-150 C6701-167		UNIT
			MIN	MAX	
1	t _{c(CKO2)}	Cycle time, CLKOUT2	2P - 0.7	2P + 0.7	ns
2	t _{w(CKO2H)}	Pulse duration, CLKOUT2 high	P – 0.7	P + 0.7	ns
3	t _{w(CKO2L)}	Pulse duration, CLKOUT2 low	P – 0.7	P + 0.7	ns
4	t _{t(CKO2)}	Transition time, CLKOUT2		0.6	ns

 $[\]S$ P = 1/CPU clock frequency in ns.

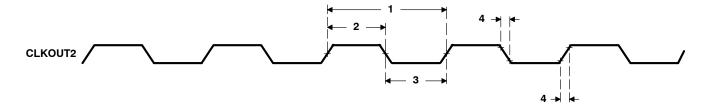


Figure 12. CLKOUT2 Timings

INPUT AND OUTPUT CLOCKS (CONTINUED)

SDCLK, SSCLK timing parameters

SDCLK timing parameters are the same as CLKOUT2 parameters.

SSCLK timing parameters are the same as CLKOUT1 or CLKOUT2 parameters, depending on SSCLK configuration.

switching characteristics for the relation of SSCLK, SDCLK, and CLKOUT2 to CLKOUT1 (see Figure 13)

NO.	PARAMETER		C6701	C6701-120 C6701-150 C6701-167	
		MIN	MAX		
1	t _d (CKO1-SSCLK)	Delay time, CLKOUT1 edge to SSCLK edge	-0.8	3.4	ns
2	t _d (CKO1-SSCLK1/2)	Delay time, CLKOUT1 edge to SSCLK edge (1/2 clock rate)	-1.0	3.0	ns
3	t _{d(CKO1-CKO2)}	Delay time, CLKOUT1 edge to CLKOUT2 edge	-1.5	2.5	ns
4	t _d (CKO1-SDCLK)	Delay time, CLKOUT1 edge to SDCLK edge	-1.5	1.9	ns

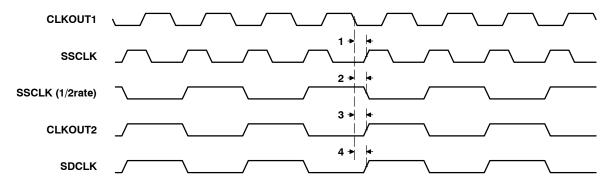


Figure 13. Relation of CLKOUT2, SDCLK, and SSCLK to CLKOUT1

ASYNCHRONOUS MEMORY TIMING

timing requirements for asynchronous memory cycles[†] (see Figure 14 and Figure 15)

NO.			C6701-120 C6701-150 C6701-167		UNIT
			MIN	MAX	
6	t _{su(EDV-CKO1H)}	Setup time, read EDx valid before CLKOUT1 high	4.5		ns
7	t _{h(CKO1H-EDV)}	Hold time, read EDx valid after CLKOUT1 high	1.5		ns
10	t _{su(ARDY-CKO1H)}	Setup time, ARDY valid before CLKOUT1 high	3.5		ns
11	th(CKO1H-ARDY)	Hold time, ARDY valid after CLKOUT1 high	1.5		ns

[†] To ensure data setup time, simply program the strobe width wide enough. ARDY is internally synchronized. If ARDY does meet setup or hold time, it may be recognized in the current cycle or the next cycle. Thus, ARDY can be an asynchronous input.

switching characteristics for asynchronous memory cycles[‡] (see Figure 14 and Figure 15)

NO.	PARAMETER		C6701-120 C6701-150 C6701-167		UNIT
			MIN	MAX	
1	t _{d(CKO1H-CEV)}	Delay time, CLKOUT1 high to CEx valid	-1.0	4.5	ns
2	t _d (CKO1H-BEV)	Delay time, CLKOUT1 high to BEx valid		4.5	ns
3	t _d (CKO1H-BEIV)	Delay time, CLKOUT1 high to BEx invalid	-1.0		ns
4	t _d (CKO1H-EAV)	Delay time, CLKOUT1 high to EAx valid		4.5	ns
5	t _{d(CKO1H-EAIV)}	Delay time, CLKOUT1 high to EAx invalid	-1.0		ns
8	t _d (CKO1H-AOEV)	Delay time, CLKOUT1 high to AOE valid	-1.0	4.5	ns
9	t _{d(CKO1H-AREV)}	Delay time, CLKOUT1 high to ARE valid	-0.5	4.5	ns
12	t _{d(CKO1H-EDV)}	Delay time, CLKOUT1 high to EDx valid		4.5	ns
13	t _d (CKO1H-EDIV)	Delay time, CLKOUT1 high to EDx invalid	-1.0		ns
14	t _d (CKO1H-AWEV)	Delay time, CLKOUT1 high to AWE valid	-1.0	4.5	ns

[‡] The minimum delay is also the minimum output hold after CLKOUT1 high.

ASYNCHRONOUS MEMORY TIMING (CONTINUED)

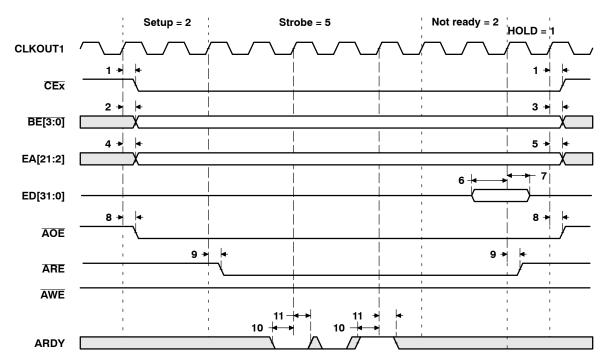


Figure 14. Asynchronous Memory Read Timing

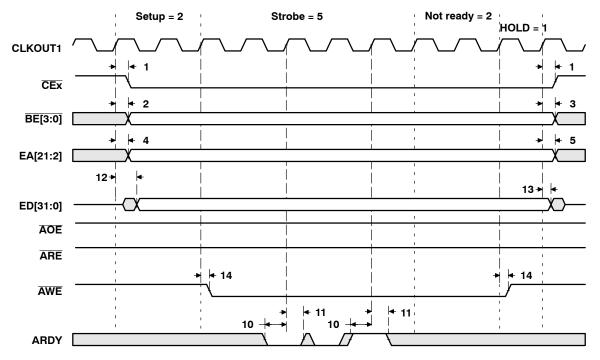


Figure 15. Asynchronous Memory Write Timing



SYNCHRONOUS-BURST MEMORY TIMING

timing requirements for synchronous-burst SRAM cycles (full-rate SSCLK) (see Figure 16)

NO.			'C670	1-120	C6701-150 C6701-167		UNIT
			MIN	MAX	MIN	MAX	
7	t _{su(EDV-SSCLKH)}	Setup time, read EDx valid before SSCLK high	2.0		2.0		ns
8	t _{h(SSCLKH-EDV)}	Hold time, read EDx valid after SSCLK high	2.9		2.1		ns

switching characteristics for synchronous-burst SRAM cycles[†] (full-rate SSCLK) (see Figure 16 and Figure 17)

NO.		PARAMETER		'C6701-120		C6701-150 C6701-167	
			MIN	MAX	MIN	MAX	
1	t _{osu(CEV-SSCLKH)}	Output setup time, CEx valid before SSCLK high	0.5P - 1.3		0.5P - 1.3		ns
2	t _{oh(SSCLKH-CEV)}	Output hold time, CEx valid after SSCLK high	0.5P - 2.9		0.5P - 2.3		ns
3	t _{osu(BEV-SSCLKH)}	Output setup time, BEx valid before SSCLK high	0.5P - 1.3		0.5P - 1.6		ns
4	t _{oh(SSCLKH-BEIV)}	Output hold time, BEx invalid after SSCLK high	0.5P - 2.9		0.5P - 2.3		ns
5	t _{osu(EAV-SSCLKH)}	Output setup time, EAx valid before SSCLK high	0.5P - 1.3		0.5P - 1.7		ns
6	toh(SSCLKH-EAIV)	Output hold time, EAx invalid after SSCLK high	0.5P - 2.9		0.5P - 2.3		ns
9	t _{osu(ADSV-SSCLKH)}	Output setup time, SSADS valid before SSCLK high	0.5P - 1.3		0.5P - 1.3		ns
10	toh(SSCLKH-ADSV)	Output hold time, SSADS valid after SSCLK high	0.5P - 2.9		0.5P - 2.3		ns
11	t _{osu(OEV-SSCLKH)}	Output setup time, SSOE valid before SSCLK high	0.5P - 1.3		0.5P - 1.3		ns
12	t _{oh(SSCLKH-OEV)}	Output hold time, SSOE valid after SSCLK high	0.5P - 2.9		0.5P - 2.3		ns
13	t _{osu(EDV-SSCLKH)}	Output setup time, EDx valid before SSCLK high	0.5P - 1.3		0.5P - 1.3		ns
14	toh(SSCLKH-EDIV)	Output hold time, EDx invalid after SSCLK high	0.5P - 2.9		0.5P - 2.3		ns
15	t _{osu(WEV-SSCLKH)}	Output setup time, SSWE valid before SSCLK high	0.5P - 1.3		0.5P - 1.3		ns
16	t _{oh(SSCLKH-WEV)}	Output hold time, SSWE valid after SSCLK high	0.5P - 2.9		0.5P - 2.3		ns

[†] When the PLL is used (CLKMODE x4), P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns. For CLKMODE x1, 0.5P is defined as PH (pulse duration of CLKIN high) for all output setup times; 0.5P is defined as PL (pulse duration of CLKIN low) for all output hold times.

SYNCHRONOUS-BURST MEMORY TIMING (CONTINUED)

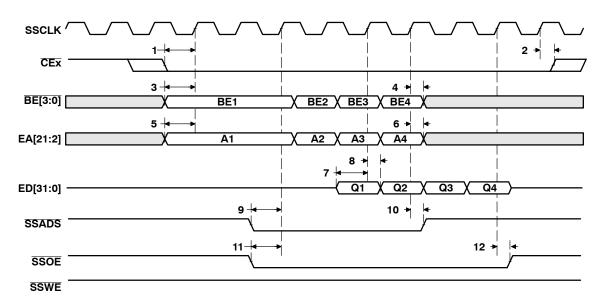


Figure 16. SBSRAM Read Timing (Full-Rate SSCLK)

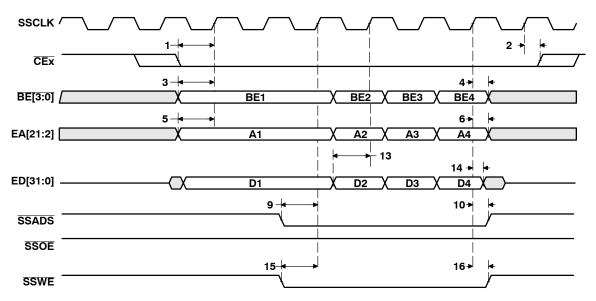


Figure 17. SBSRAM Write Timing (Full-Rate SSCLK)

SYNCHRONOUS-BURST MEMORY TIMING (CONTINUED)

timing requirements for synchronous-burst SRAM cycles (half-rate SSCLK) (see Figure 18)

NO.			C670 C670 C670 MIN	1-150	UNIT
7	t _{su(EDV-SSCLKH)}	Setup time, read EDx valid before SSCLK high	3.6		ns
8	t _{h(SSCLKH-EDV)}	Hold time, read EDx valid after SSCLK high	1.5		ns

switching characteristics for synchronous-burst SRAM cycles[†] (half-rate SSCLK) (see Figure 18 and Figure 19)

NO.	PARAMETER		C6701-120		C6701-150 C6701-167		UNIT
			MIN	MAX	MIN	MAX	
1	t _{osu(CEV-SSCLKH)}	Output setup time, CEx valid before SSCLK high	1.5P – 4.5		1.5P – 4.5		ns
2	toh(SSCLKH-CEV)	Output hold time, CEx valid after SSCLK high	0.5P - 2.5		0.5P - 2		ns
3	t _{osu(BEV-SSCLKH)}	Output setup time, BEx valid before SSCLK high	1.5P – 4.5		1.5P – 4.5		ns
4	toh(SSCLKH-BEIV)	Output hold time, BEx invalid after SSCLK high	0.5P - 2.5		0.5P - 2		ns
5	t _{osu(EAV-SSCLKH)}	Output setup time, EAx valid before SSCLK high	1.5P – 4.5		1.5P – 4.5		ns
6	toh(SSCLKH-EAIV)	Output hold time, EAx invalid after SSCLK high	0.5P - 2.5		0.5P - 2		ns
9	t _{osu(ADSV-SSCLKH)}	Output setup time, SSADS valid before SSCLK high	1.5P – 4.5		1.5P – 4.5		ns
10	toh(SSCLKH-ADSV)	Output hold time, SSADS valid after SSCLK high	0.5P - 2.5		0.5P - 2		ns
11	t _{osu(OEV-SSCLKH)}	Output setup time, SSOE valid before SSCLK high	1.5P – 4.5		1.5P – 4.5		ns
12	toh(SSCLKH-OEV)	Output hold time, SSOE valid after SSCLK high	0.5P - 2.5		0.5P - 2		ns
13	t _{osu(EDV-SSCLKH)}	Output setup time, EDx valid before SSCLK high	1.5P – 4.5		1.5P – 4.5		ns
14	toh(SSCLKH-EDIV)	Output hold time, EDx invalid after SSCLK high	0.5P - 2.5		0.5P – 2		ns
15	t _{osu(WEV-SSCLKH)}	Output setup time, SSWE valid before SSCLK high	1.5P – 4.5	•	1.5P – 4.5		ns
16	toh(SSCLKH-WEV)	Output hold time, SSWE valid after SSCLK high	0.5P - 2.5		0.5P – 2		ns

[†] When the PLL is used (CLKMODE x4), P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns. For CLKMODE x1:

^{1.5}P = P + PH, where P = 1/CPU clock frequency, and PH = pulse duration of CLKIN high.

^{0.5}P = PL, where PL = pulse duration of CLKIN low.

SYNCHRONOUS-BURST MEMORY TIMING (CONTINUED)

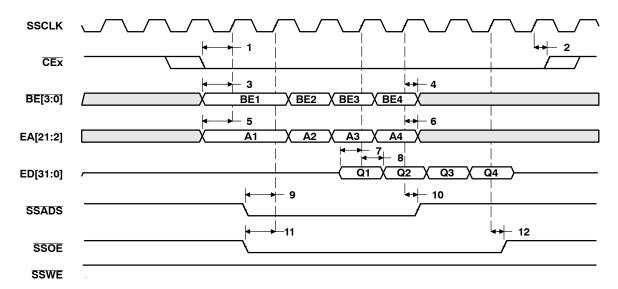


Figure 18. SBSRAM Read Timing (1/2 Rate SSCLK)

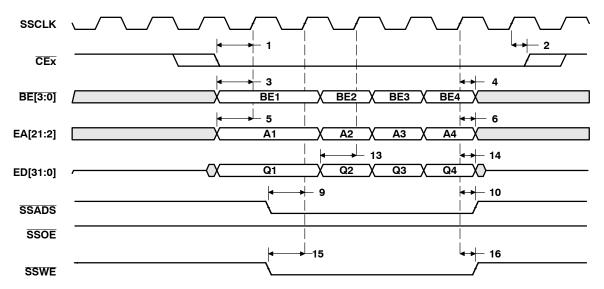


Figure 19. SBSRAM Write Timing (1/2 Rate SSCLK)

SYNCHRONOUS DRAM TIMING

timing requirements for synchronous DRAM cycles (see Figure 20)

NO.		C6701 C6701 C6701	I-150	UNIT
		MIN	MAX	
7	t _{su(EDV-SDCLKH)} Setup time, read EDx valid before SDCLK high	1.8		ns
8	t _{h(SDCLKH-EDV)} Hold time, read EDx valid after SDCLK high	3		ns

switching characteristics for synchronous DRAM cycles[†] (see Figure 20-Figure 25)

NO.		PARAMETER	C6701-1	20	C6701-1 C6701-1		UNIT
			MIN	MAX	MIN	MAX	
1	t _{osu(CEV-SDCLKH)}	Output setup time, CEx valid before SDCLK high	1.5P – 4		1.5P – 4		ns
2	toh(SDCLKH-CEV)	Output hold time, CEx valid after SDCLK high	0.5P - 1.9		0.5P - 1.5		ns
3	t _{osu(BEV-SDCLKH)}	Output setup time, BEx valid before SDCLK high	1.5P – 4		1.5P – 4		ns
4	toh(SDCLKH-BEIV)	Output hold time, BEx invalid after SDCLK high	0.5P - 1.9		0.5P - 1.5		ns
5	t _{osu(EAV-SDCLKH)}	Output setup time, EAx valid before SDCLK high	1.5P – 4		1.5P – 4		ns
6	toh(SDCLKH-EAIV)	Output hold time, EAx invalid after SDCLK high	0.5P - 1.9		0.5P - 1.5		ns
9	t _{osu(SDCAS-SDCLKH)}	Output setup time, SDCAS valid before SDCLK high	1.5P – 4		1.5P – 4		ns
10	toh(SDCLKH-SDCAS)	Output hold time, SDCAS valid after SDCLK high	0.5P - 1.9		0.5P - 1.5		ns
11	t _{osu(EDV-SDCLKH)}	Output setup time, EDx valid before SDCLK high	1.5P – 4		1.5P – 4		ns
12	toh(SDCLKH-EDIV)	Output hold time, EDx invalid after SDCLK high	0.5P - 1.9		0.5P - 1.5		ns
13	t _{osu(SDWE-SDCLKH)}	Output setup time, SDWE valid before SDCLK high	1.5P – 4		1.5P – 4		ns
14	toh(SDCLKH-SDWE)	Output hold time, SDWE valid after SDCLK high	0.5P - 1.9		0.5P - 1.5		ns
15	t _{osu(SDA10V-SDCLKH)}	Output setup time, SDA10 valid before SDCLK high	1.5P – 4		1.5P – 4		ns
16	t _{oh(SDCLKH-SDA10IV)}	Output hold time, SDA10 invalid after SDCLK high	0.5P - 1.9		0.5P - 1.5		ns
17	t _{osu(SDRAS-SDCLKH)}	Output setup time, SDRAS valid before SDCLK high	1.5P – 4		1.5P – 4		ns
18	toh(SDCLKH-SDRAS)	Output hold time, SDRAS valid after SDCLK high	0.5P - 1.9		0.5P - 1.5		ns

[†] When the PLL is used (CLKMODE x4), P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns. For CLKMODE x1:

^{1.5}P = P + PH, where P = 1/CPU clock frequency, and PH = pulse duration of CLKIN high.

^{0.5}P = PL, where PL = pulse duration of CLKIN low.

SYNCHRONOUS DRAM TIMING (CONTINUED)

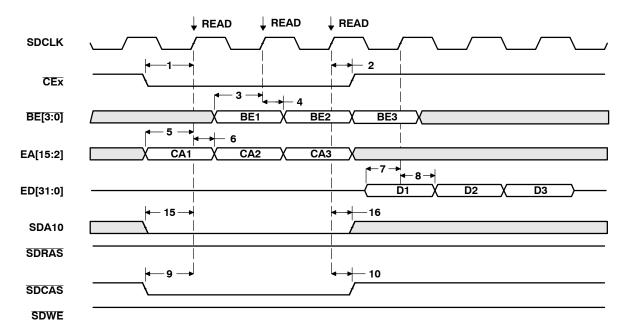


Figure 20. Three SDRAM Read Commands

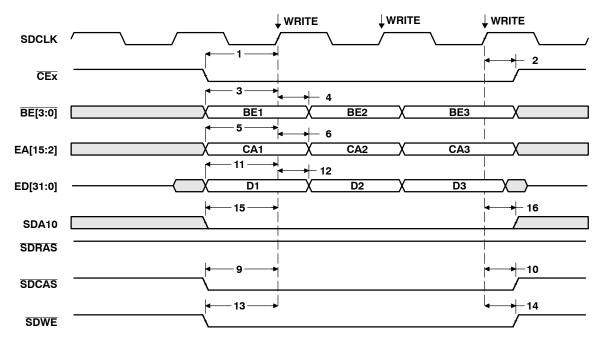


Figure 21. Three SDRAM Write Commands



SYNCHRONOUS DRAM TIMING (CONTINUED)

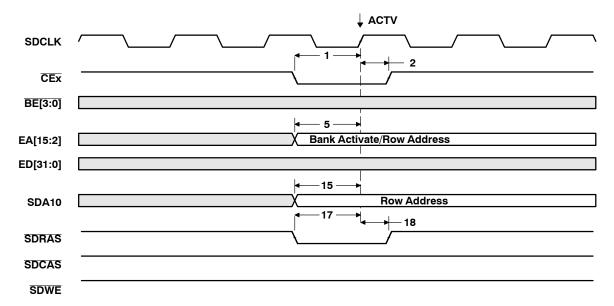


Figure 22. SDRAM ACTV Command

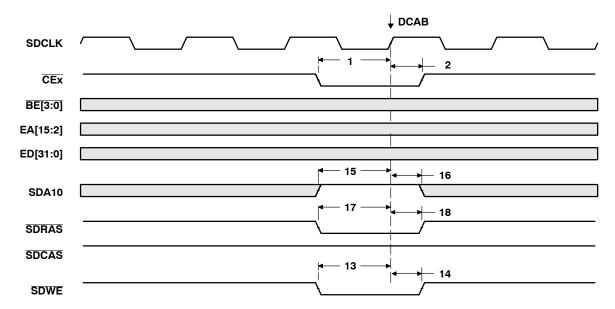


Figure 23. SDRAM DCAB Command

SYNCHRONOUS DRAM TIMING (CONTINUED)

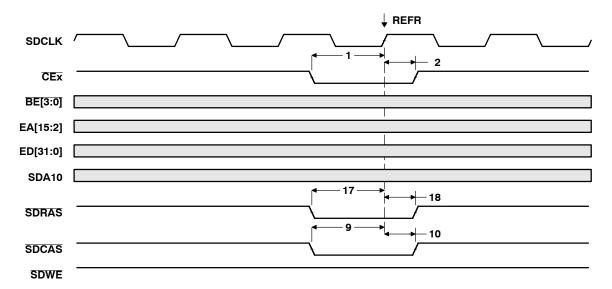


Figure 24. SDRAM REFR Command

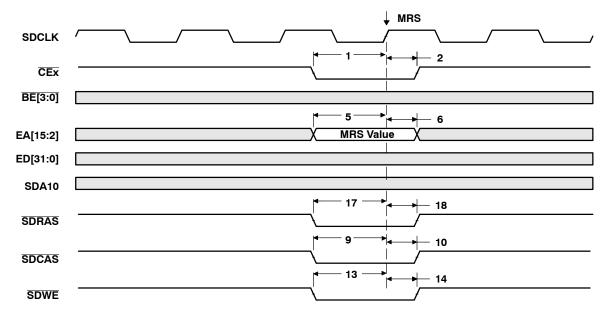


Figure 25. SDRAM MRS Command

HOLD/HOLDA TIMING

timing requirements for the hold/hold acknowledge cycles[†] (see Figure 26)

NO.			C6701-120 C6701-150 C6701-167	
		MIN	MAX	
1	t _{su(HOLDH-CKO1H)} Setup time, HOLD high before CLKOUT1	nigh 5		ns
2	t _{h(CKO1H-HOLDL)} Hold time, HOLD low after CLKOUT1 high	2		ns

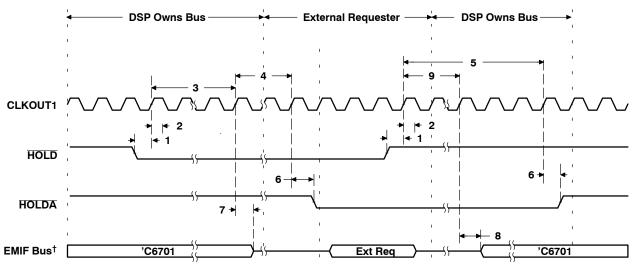
[†] HOLD is synchronized internally. Therefore, if setup and hold times are not met, it will either be recognized in the current cycle or in the next cycle. Thus, HOLD can be an asynchronous input.

switching characteristics for the hold/hold acknowledge cycles[‡] (see Figure 26)

NO.	PARAMETER		C6701 C6701 C6701	UNIT	
			MIN	MAX	
3	t _{R(HOLDL-EMHZ)}	Response time, HOLD low to EMIF high impedance	4P	§	ns
4	t _{R(EMHZ-HOLDAL)}	Response time, EMIF high impedance to HOLDA low		2P	ns
5	t _{R(HOLDH-HOLDAH)}	Response time, HOLD high to HOLDA high	4P	7P	ns
6	t _d (CKO1H-HOLDAL)	Delay time, CLKOUT1 high to HOLDA valid	1	8	ns
7	t _d (CKO1H-BHZ)	Delay time, CLKOUT1 high to EMIF Bus high impedance [¶]	1	8	ns
8	t _{d(CKO1H-BLZ)}	Delay time, CLKOUT1 high to EMIF Bus low impedance [¶]	1	12	ns
9	t _{R(HOLDH-BLZ)}	Response time, HOLD high to EMIF Bus low impedance [¶]	3P	6P	ns

[‡] P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns.

[¶] EMIF Bus consists of CE[3:0], BE[3:0], ED[31:0], EA[21:2], ARE, AOE, AWE, SSADS, SSOE, SSWE, SDA10, SDRAS, SDCAS, and SDWE.



[†] EMIF Bus consists of CE[3:0], BE[3:0], ED[31:0], EA[21:2], ARE, AOE, AWE, SSADS, SSOE, SSWE, SDA10, SDRAS, SDCAS, and SDWE.

Figure 26. HOLD/HOLDA Timing

[§] All pending EMIF transactions are allowed to complete before HOLDA is asserted. The worst cases for this is an asynchronous read or write with external ARDY used or a minimum of eight consecutive SDRAM reads or writes when RBTR8 = 1. If no bus transactions are occurring, then the minimum delay time can be achieved. Also, bus hold can be indefinitely delayed by setting the NOHOLD = 1.

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RESET TIMING

timing requirements for reset (see Figure 27)

NO.			C6701 C6701 C6701	-150	UNIT
			MIN	MAX	
1	t _{w(RESET)}	Width of the RESET pulse (PLL stable)†	10		CLKOUT1 cycles
	(,	Width of the RESET pulse (PLL needs to sync up) [‡]	250		μs

[†] This parameter applies to CLKMODE x1 when CLKIN is stable and applies to CLKMODE x4 when CLKIN and PLL are stable.

switching characteristics during reset§¶ (see Figure 27)

NO.		PARAMETER	C6701 C6701 C6701	-150	UNIT
			MIN	MAX	
2	t _{R(RESET)}	Response time to change of value in RESET signal	1		CLKOUT1 cycles
3	t _{d(CKO1H-CKO2IV)}	Delay time, CLKOUT1 high to CLKOUT2 invalid	-1		ns
4	t _{d(CKO1H-CKO2V)}	Delay time, CLKOUT1 high to CLKOUT2 valid		10	ns
5	t _d (CKO1H-SDCLKIV)	Delay time, CLKOUT1 high to SDCLK invalid	-1		ns
6	t _d (CKO1H-SDCLKV)	Delay time, CLKOUT1 high to SDCLK valid		10	ns
7	t _d (CKO1H-SSCKIV)	Delay time, CLKOUT1 high to SSCLK invalid	-1		ns
8	t _{d(CKO1H-SSCKV)}	Delay time, CLKOUT1 high to SSCLK valid		10	ns
9	t _{d(CKO1H-LOWIV)}	Delay time, CLKOUT1 high to low group invalid	-1		ns
10	t _{d(CKO1H-LOWV)}	Delay time, CLKOUT1 high to low group valid		10	ns
11	t _d (CKO1H-HIGHIV)	Delay time, CLKOUT1 high to high group invalid	-1		ns
12	t _d (CKO1H-HIGHV)	Delay time, CLKOUT1 high to high group valid		10	ns
13	t _d (CKO1H-ZHZ)	Delay time, CLKOUT1 high to Z group high impedance	-1		ns
14	t _{d(CKO1H-ZV)}	Delay time, CLKOUT1 high to Z group valid		10	ns

[§] Low group consists of: IACK, INUM[3:0], DMAC[3:0], PD, TOUT0, and TOUT1.

High group consists of: HIN

Z group consists of: EA[21:2], ED[31:0], CE[3:0], BE[3:0], ARE, AWE, AOE, SSADS, SSOE, SSWE, SDA10, SDRAS, SDCAS,

SDWE, HD[15:0], CLKX0, CLKX1, FSX0, FSX1, DX0, DX1, CLKR0, CLKR1, FSR0, and FSR1.

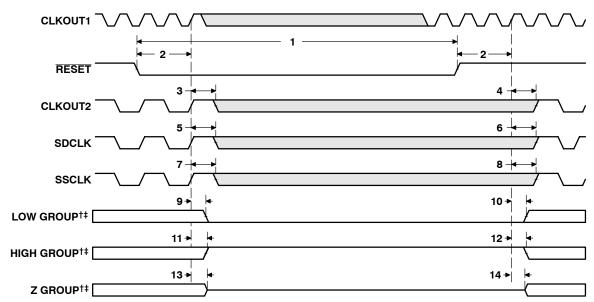
If \overline{HCS} = 0 at device reset, \overline{HRDY} belongs to the high group.

If $\overline{HCS} = 1$ at device reset, \overline{HRDY} belongs to the low group.

[‡] This parameter only applies to CLKMODE x4. The RESET signal is not connected internally to the clock PLL circuit. The PLL, however, may need up to 250 µs to stabilize following device powerup or after PLL configuration has been changed. During that time, RESET must be asserted to ensure proper device operation. See the *clock PLL* section for PLL lock times.

[¶] HRDY is gated by input HCS.

RESET TIMING (CONTINUED)



[†] Low group consists of: High group consists of: IACK, INUM[3:0], DMAC[3:0], PD, TOUT0, and TOUT1.

Z group consists of:

EA[21:2], ED[31:0], CE[3:0], BE[3:0], ARE, AWE, AOE, SSADS, SSOE, SSWE, SDA10, SDRAS, SDCAS,

SDWE, HD[15:0], CLKX0, CLKX1, FSX0, FSX1, DX0, DX1, CLKR0, CLKR1, FSR0, and FSR1.

 ‡ $\overline{\text{HRDY}}$ is gated by input $\overline{\text{HCS}}.$

If $\overline{HCS} = 0$ at device reset, \overline{HRDY} belongs to the high group.

If HCS = 1 at device reset, HRDY belongs to the low group.

Figure 27. Reset Timing

EXTERNAL INTERRUPT TIMING

timing requirements for interrupt response cycles^{†‡} (see Figure 28)

NO.		C6701 C6701 C6701	-150	UNIT
		MIN	MAX	
2	$t_{w(ILOW)}$ Width of the interrupt pulse low	2P		ns
3	t _{w(IHIGH)} Width of the interrupt pulse high	2P		ns

[†] Interrupt signals are synchronized internally and are potentially recognized one cycle later if setup and hold times are violated. Thus, they can be connected to asynchronous inputs.

switching characteristics during interrupt response cycles§ (see Figure 28)

NO.	. PARAMETER		C67 C67 C67	UNIT	
			MIN	MAX	
1	t _R (EINTH-IACKH)	Response time, EXT_INTx high to IACK high	9P		ns
4	t _d (CKO2L-IACKV)	Delay time, CLKOUT2 low to IACK valid	-0.5P	13 – 0.5P	ns
5	t _{d(CKO2L-INUMV)}	Delay time, CLKOUT2 low to INUMx valid		10 – 0.5P	ns
6	t _{d(CKO2L-INUMIV)}	Delay time, CLKOUT2 low to INUMx invalid	-0.5P		ns

 $[\]S$ P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns. When the PLL is used (CLKMODE x4), 0.5P = 1/(2 × CPU clock frequency). For CLKMODE x1: 0.5P = PH, where PH is the high period of CLKIN.

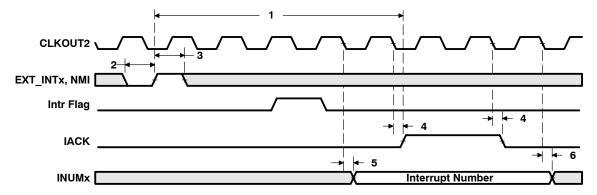


Figure 28. Interrupt Timing

 $^{^{\}ddagger}$ P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns.

HOST-PORT INTERFACE TIMING

timing requirements for host-port interface cycles^{†‡} (see Figure 29, Figure 30, Figure 31, and Figure 32)

NO.			C6701 C6701 C6701	UNIT	
			MIN	MAX	
1	t _{su(SEL-HSTBL)}	Setup time, select signals§ valid before HSTROBE low	4		ns
2	t _{h(HSTBL-SEL)}	Hold time, select signals [§] valid after HSTROBE low	2		ns
3	t _{w(HSTBL)}	Pulse duration, HSTROBE low	2P		ns
4	t _{w(HSTBH)}	Pulse duration, HSTROBE high between consecutive accesses	2P		ns
10	t _{su(SEL-HASL)}	Setup time, select signals§ valid before HAS low	4		ns
11	t _{h(HASL-SEL)}	Hold time, select signals [§] valid after HAS low	2		ns
12	t _{su(HDV-HSTBH)}	Setup time, host data valid before HSTROBE high	3		ns
13	t _{h(HSTBH-HDV)}	Hold time, host data valid after HSTROBE high	2		ns
14	t _{h(HRDYL-HSTBL)}	Hold time, HSTROBE low after HRDY low. HSTROBE should not be inactivated until HRDY is active (low); otherwise, HPI writes will not complete properly.	1		ns
18	t _{su(HASL-HSTBL)}	Setup time, HAS low before HSTROBE low	2		ns
19	t _{h(HSTBL-HASL)}	Hold time, HAS low after HSTROBE low	2		ns

[†] HSTROBE refers to the following logical operation on HCS, HDS1, and HDS2: [NOT(HDS1 XOR HDS2)] OR HCS.

switching characteristics during host-port interface cycles^{†‡} (see Figure 29, Figure 30, Figure 31, and Figure 32)

NO.	PARAMETER		C670 C670 C670	UNIT	
			MIN	MAX	
5	t _{d(HCS-HRDY)}	Delay time, HCS to HRDY¶	1	12	ns
6	t _{d(HSTBL-HRDYH)}	Delay time, HSTROBE low to HRDY high#	1	12	ns
7	t _{d(HSTBL-HDLZ)}	Delay time, HSTROBE low to HD low impedance for an HPI read	4		ns
8	t _{d(HDV-HRDYL)}	Delay time, HD valid to HRDY low	P – 3	P + 3	ns
9	toh(HSTBH-HDV)	Output hold time, HD valid after HSTROBE high	3	12	ns
15	t _{d(HSTBH-HDHZ)}	Delay time, HSTROBE high to HD high impedance	3	12	ns
16	t _{d(HSTBL-HDV)}	Delay time, HSTROBE low to HD valid	3	12	ns
17	t _{d(HSTBH-HRDYH)}	Delay time, HSTROBE high to HRDY high	1	12	ns
20	t _{d(HASL-HRDYH)}	Delay time, HAS low to HRDY high	3	12	ns

[†] HSTROBE refers to the following logical operation on HCS, HDS1, and HDS2: [NOT(HDS1 XOR HDS2)] OR HCS.



 $^{^{\}ddagger}$ P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns.

[§] Select signals include: HCNTRL[1:0], HR/W, and HHWIL.

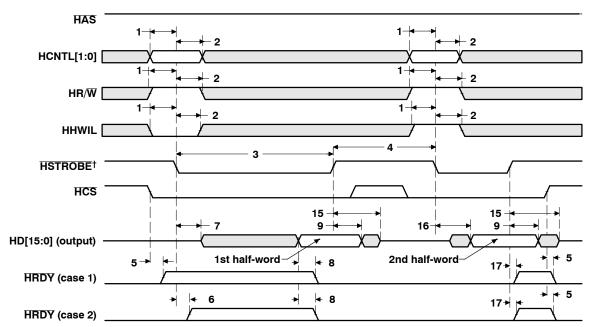
 $^{^{\}ddagger}$ P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns.

HCS enables HRDY, and HRDY is always low when HCS is high. The case where HRDY goes high when HCS falls indicates that HPI is busy completing a previous HPID write or READ with autoincrement.

[#] This parameter is used during an HPID read. At the beginning of the first half-word transfer on the falling edge of HSTROBE, the HPI sends the request to the DMA auxiliary channel, and HRDY remains high until the DMA auxiliary channel loads the requested data into HPID.

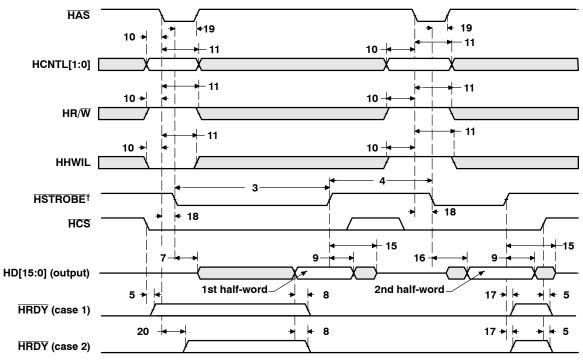
This parameter is used after the second half-word of an HPID write or autoincrement read. HRDY remains low if the access is not an HPID write or autoincrement read. Reading or writing to HPIC or HPIA does not affect the HRDY signal.

HOST-PORT INTERFACE TIMING (CONTINUED)



[†] HSTROBE refers to the following logical operation on HCS, HDS1, and HDS2: [NOT(HDS1 XOR HDS2)] OR HCS.

Figure 29. HPI Read Timing (HAS Not Used, Tied High)

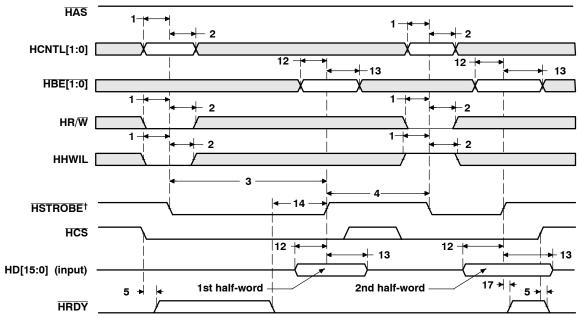


[†] HSTROBE refers to the following logical operation on HCS, HDS1, and HDS2: [NOT(HDS1 XOR HDS2)] OR HCS.

Figure 30. HPI Read Timing (HAS Used)

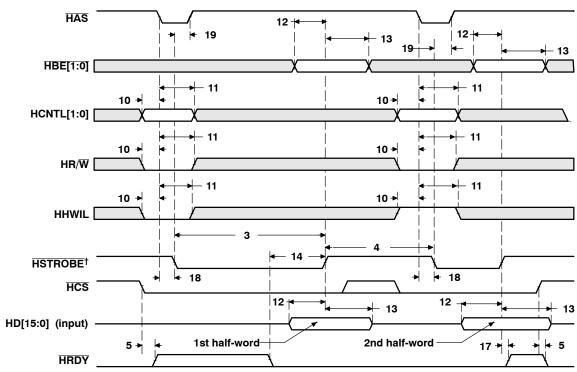


HOST-PORT INTERFACE TIMING (CONTINUED)



[†] HSTROBE refers to the following logical operation on HCS, HDS1, and HDS2: [NOT(HDS1 XOR HDS2)] OR HCS.

Figure 31. HPI Write Timing (HAS Not Used, Tied High)



[†] HSTROBE refers to the following logical operation on HCS, HDS1, and HDS2: [NOT(HDS1 XOR HDS2)] OR HCS.

Figure 32. HPI Write Timing (HAS Used)



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MULTICHANNEL BUFFERED SERIAL PORT TIMING

timing requirements for McBSP^{†‡} (see Figure 33)

NO.				C6701 C6701 C6701	-150	UNIT
				MIN	MAX	
2	t _{c(CKRX)}	Cycle time, CLKR/X	CLKR/X ext	2P [§]		ns
3	t _{w(CKRX)}	Pulse duration, CLKR/X high or CLKR/X low	CLKR/X ext	P – 1 [¶]		ns
-	t _{su(FRH-CKRL)}	Setup time, external FSR high before CLKR low	CLKR int	13		
5			CLKR ext	4		ns
_	t _{h(CKRL-FRH)}	Hold time, external FSR high after CLKR low	CLKR int	7		
6			CLKR ext	4		ns
_			CLKR int	10		
7	t _{su(DRV-CKRL)}	Setup time, DR valid before CLKR low	CLKR ext	1		ns
•		Halding DD and after OHO Is	CLKR int	4		
8	t _{h(CKRL-DRV)}	Hold time, DR valid after CLKR low	CLKR ext	4		ns
40	1.	0.1 - 1 1 FOV habitation OLIGIT	CLKX int	13		
10	t _{su(FXH-CKXL)}	Setup time, external FSX high before CLKX low	CLKX ext	4		ns
44	t _{h(CKXL-FXH)}	VI EVID. Hold time, external FSX high after CLKX low	CLKX int	7		
11			CLKX ext	3		ns

[†] P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns.

[‡] CLKRP = CLKXP = FSRP = FSXP = 0. If polarity of any of the signals is inverted, then the timing references of that signal are also inverted.

[§] The maximum McBSP bit rate is 50 MHz; therefore, the minimum CLKR/X clock cycle is either twice the CPU cycle time (2P), or 20 ns (50 MHz), whichever value is larger. For example, when running parts at 167 MHz (P = 6 ns), use 20 ns as the minimum CLKR/X clock cycle (by setting the appropriate CLKGDV ratio or external clock source). When running parts at 80 MHz (P = 12.5 ns), use 2P = 25 ns (40 MHz) as the minimum CLKR/X clock cycle. The maximum McBSP bit rate applies when the serial port is a master of clock and frame syncs and the other device the McBSP communicates to is a slave.

The minimum CLKR/X pulse duration is either (P-1) or 9 ns, whichever is larger. For example, when running parts at 167 MHz (P = 6 ns), use 9 ns as the minimum CLKR/X pulse duration. When running parts at 80 MHz (P = 12.5 ns), use (P-1) = 11.5 ns as the minimum CLKR/X pulse duration.

switching characteristics for McBSP^{†‡} (see Figure 33)

NO.		C670 C670 C670	UNIT			
				MIN	MAX	
1	Delay time, CLKS high to CLKR/X high for internal CLKR/X generated from CLKS input				15	ns
2	t _{c(CKRX)}	Cycle time, CLKR/X	CLKR/X int	2P ^{§¶}		ns
3	t _{w(CKRX)}	Pulse duration, CLKR/X high or CLKR/X low	CLKR/X int	C – 1 [#]	C + 1#	ns
4	t _{d(CKRH-FRV)}	Delay time, CLKR high to internal FSR valid	CLKR int	-4	4	ns
		Dalantina OLIV high to internal FOV nalid	CLKX int	-4	5	
9	t _d (CKXH-FXV)	Delay time, CLKX high to internal FSX valid	CLKX ext	3	16	ns
40		Disable time, DX high impedance following last data bit from	CLKX int	-3	2	
12	^t dis(CKXH-DXHZ)	CLKX high	CLKX ext	2	9	ns
40		Data than OHOV balance DV and	CLKX int	-2	4	
13	t _d (CKXH-DXV)	Delay time, CLKX high to DX valid.	CLKX ext	3	16	ns
4.4	t _{d(FXH-DXV)}	Delay time, FSX high to DX valid. ONLY applies when in data delay 0 (XDATDLY = 00b) mode.	FSX int	-2	4	
14			FSX ext	2	10	ns

[†] CLKRP = CLKXP = FSRP = FSXP = 0. If polarity of any of the signals is inverted, then the timing references of that signal are also inverted.

S = sample rate generator input clock = P if CLKSM = 1 (P = 1/CPU clock frequency)

= sample rate generator input clock = P clks if CLKSM = 0 (P clks = CLKS period)

H = CLKX high pulse width = (CLKGDV/2 + 1) * S if CLKGDV is even

= (CLKGDV + 1)/2 * S if CLKGDV is odd or zero

L = CLKX low pulse width = (CLKGDV/2) * S if CLKGDV is even

= (CLKGDV + 1)/2 * S if CLKGDV is odd or zero

CLKGDV should be set appropriately to ensure the McBSP bit rate does not exceed the 50 MHz limit.



[‡] Minimum delay times also represent minimum output hold times.

 $^{^{\}S}$ P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns.

The maximum McBSP bit rate is 50 MHz; therefore, the minimum CLKR/X clock cycle is either twice the CPU cycle time (2P), or 20 ns (50 MHz), whichever value is larger. For example, when running parts at 167 MHz (P = 6 ns), use 20 ns as the minimum CLKR/X clock cycle (by setting the appropriate CLKGDV ratio or external clock source). When running parts at 80 MHz (P = 12.5 ns), use 2P = 25 ns (40 MHz) as the minimum CLKR/X clock cycle. The maximum McBSP bit rate applies when the serial port is a master of clock and frame syncs and the other device the McBSP communicates to is a slave.

 $^{^{\#}}$ C = H or L

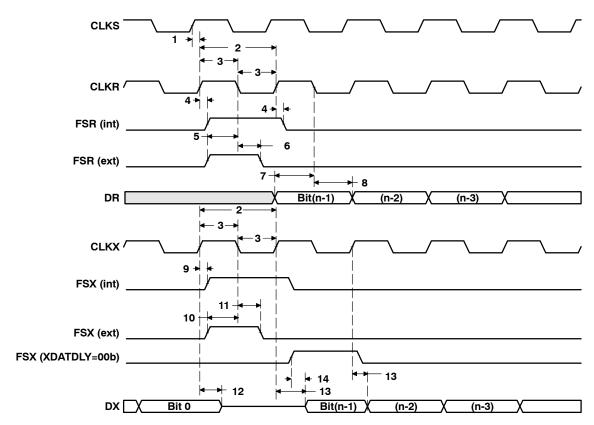


Figure 33. McBSP Timings

timing requirements for FSR when GSYNC = 1 (see Figure 34)

NO.			C6701 C6701 C6701	-150	UNIT
			MIN	MAX	
1	t _{su(FRH-CKSH)}	Setup time, FSR high before CLKS high	4		ns
2	t _{h(CKSH-FRH)}	Hold time, FSR high after CLKS high	4		ns

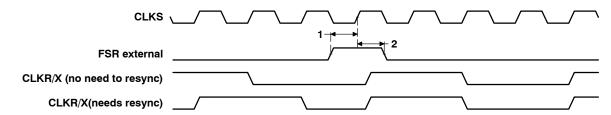


Figure 34. FSR Timing When GSYNC = 1

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MULTICHANNEL BUFFERED SERIAL PORT TIMING (CONTINUED)

timing requirements for McBSP as SPI master or slave: CLKSTP = 10b, CLKXP = 0^{†‡} (see Figure 35)

NO.	NO.			UNIT			
			MASTER		SLAVE		
			MIN	MAX	MIN	MAX	
4	t _{su(DRV-CKXL)}	Setup time, DR valid before CLKX low	12		2 – 3P		ns
5	t _{h(CKXL-DRV)}	Hold time, DR valid after CLKX low	4		5 + 6P		ns

[†] P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns.

switching characteristics for McBSP as SPI master or slave: CLKSTP = 10b, CLKXP = $0^{\dagger \ddagger}$ (see Figure 35)

NO.	PARAMETER			C6701-120 C6701-150 C6701-167					
		.,	MAS	TER§	SL	UNIT			
						MAX			
1	t _{h(CKXL-FXL)}	Hold time, FSX low after CLKX low [¶]	T – 4	T + 4			ns		
2	t _{d(FXL-CKXH)}	Delay time, FSX low to CLKX high#	L – 4	L + 4			ns		
3	t _{d(CKXH-DXV)}	Delay time, CLKX high to DX valid	-4	4	3P + 1	5P + 17	ns		
6	t _{dis(CKXL-DXHZ)}	Disable time, DX high impedance following last data bit from CLKX low	L – 2	L + 3			ns		
7	t _{dis(FXH-DXHZ)}	Disable time, DX high impedance following last data bit from FSX high			P + 4	3P + 17	ns		
8	t _{d(FXL-DXV)}	Delay time, FSX low to DX valid			2P + 1	4P + 13	ns		

[†] P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns.

T = CLKX period = (1 + CLKGDV) * S

 $H = \ CLKX \ high \ pulse \ width \ = (CLKGDV/2 + 1) * S \ if \ CLKGDV \ is \ even$

= (CLKGDV + 1)/2 * S if CLKGDV is odd or zero

L = CLKX low pulse width = (CLKGDV/2) * S if CLKGDV is even

= (CLKGDV + 1)/2 * S if CLKGDV is odd or zero

CLKXM = FSXM = 1, CLKRM = FSRM = 0 for master McBSP

CLKXM = CLKRM = FSXM = FSRM = 0 for slave McBSP



[‡] For all SPI slave modes, CLKG is programmed as 1/2 of the CPU clock by setting CLKSM = CLKGDV = 1.

[‡] For all SPI slave modes, CLKG is programmed as 1/2 of the CPU clock by setting CLKSM = CLKGDV = 1.

[§] S = sample rate generator input clock = P if CLKSM = 1 (P = 1/CPU clock frequency)

⁼ sample rate generator input clock = P_clks if CLKSM = 0 (P_clks = CLKS period)

FSRP = FSXP = 1. As a SPI master, FSX is inverted to provide active-low slave-enable output. As a slave, the active-low signal input on FSX and FSR is inverted before being used internally.

[#] FSX should be low before the rising edge of clock to enable slave devices and then begin a SPI transfer at the rising edge of the master clock (CLKX).

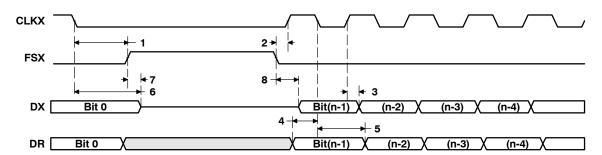


Figure 35. McBSP Timing as SPI Master or Slave: CLKSTP = 10b, CLKXP = 0

timing requirements for McBSP as SPI master or slave: CLKSTP = 11b, CLKXP = $0^{\dagger \ddagger}$ (see Figure 36)

NO.	NO.			UNIT			
			MASTER		SLAVE		
			MIN	MAX	MIN	MAX	
4	t _{su(DRV-CKXH)}	Setup time, DR valid before CLKX high	12		2 – 3P		ns
5	t _{h(CKXH-DRV)}	Hold time, DR valid after CLKX high	4		5 + 6P		ns

[†] P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns.

switching characteristics for McBSP as SPI master or slave: CLKSTP = 11b, CLKXP = 0^{†‡} (see Figure 36)

NO.	PARAMETER			UNIT			
				TER§	SL		
				MAX	MIN	MAX	
1	t _{h(CKXL-FXL)}	Hold time, FSX low after CLKX low [¶]	L – 4	L + 4			ns
2	t _{d(FXL-CKXH)}	Delay time, FSX low to CLKX high#	T – 4	T + 4			ns
3	t _{d(CKXL-DXV)}	Delay time, CLKX low to DX valid	-4	4	3P + 1	5P + 17	ns
6	t _{dis(CKXL-DXHZ)}	Disable time, DX high impedance following last data bit from CLKX low	-2	4	3P + 4	5P + 17	ns
7	t _{d(FXL-DXV)}	Delay time, FSX low to DX valid	H – 2	H + 3	2P + 1	4P + 13	ns

 $[\]frac{1}{P} = 1/CPU$ clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns.

H = CLKX high pulse width = (CLKGDV/2 + 1) * S if CLKGDV is even

= (CLKGDV + 1)/2 * S if CLKGDV is odd or zero

CLKX low pulse width = (CLKGDV/2) * S if CLKGDV is even

= (CLKGDV + 1)/2 * S if CLKGDV is odd or zero

CLKXM = FSXM = 1, CLKRM = FSRM = 0 for master McBSP

CLKXM = CLKRM = FSXM = FSRM = 0 for slave McBSP

FSX should be low before the rising edge of clock to enable slave devices and then begin a SPI transfer at the rising edge of the master clock (CLKX).

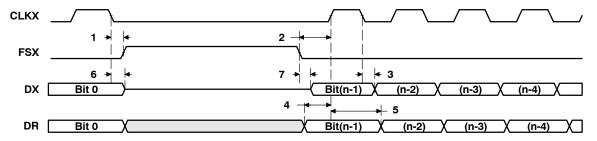


Figure 36. McBSP Timing as SPI Master or Slave: CLKSTP = 11b, CLKXP = 0



[‡] For all SPI slave modes, CLKG is programmed as 1/2 of the CPU clock by setting CLKSM = CLKGDV = 1.

[‡] For all SPI slave modes, CLKG is programmed as 1/2 of the CPU clock by setting CLKSM = CLKGDV = 1.

[§] S = sample rate generator input clock = P if CLKSM = 1 (P = 1/CPU clock frequency)

⁼ sample rate generator input clock = P_clks if CLKSM = 0 (P_clks = CLKS period)

T = CLKX period = (1 + CLKGDV) * S

[¶] FSRP = FSXP = 1. As a SPI master, FSX is inverted to provide active-low slave-enable output. As a slave, the active-low signal input on FSX and FSR is inverted before being used internally.

timing requirements for McBSP as SPI master or slave: CLKSTP = 10b, CLKXP = 1^{†‡} (see Figure 37)

NO.				C6701-120 C6701-150 C6701-167			UNIT
			MAS	MASTER		SLAVE	
			MIN	MAX	MIN	MAX	
4	t _{su(DRV-CKXH)}	Setup time, DR valid before CLKX high	12		2 – 3P		ns
5	t _{h(CKXH-DRV)}	Hold time, DR valid after CLKX high	4		5 + 6P		ns

 $^{^{\}dagger}$ P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns.

switching characteristics for McBSP as SPI master or slave: CLKSTP = 10b, CLKXP = $1^{\dagger \ddagger}$ (see Figure 37)

NO.		PARAMETER			C6701-120 C6701-150 C6701-167				
					SL	UNIT			
						MAX			
1	t _{h(CKXH-FXL)}	Hold time, FSX low after CLKX high [¶]	T – 4	T + 4			ns		
2	t _{d(FXL-CKXL)}	Delay time, FSX low to CLKX low#	H – 4	H + 4			ns		
3	t _{d(CKXL-DXV)}	Delay time, CLKX low to DX valid	-4	4	3P + 1	5P + 17	ns		
6	t _{dis(CKXH-DXHZ)}	Disable time, DX high impedance following last data bit from CLKX high	H – 2	H + 3			ns		
7	t _{dis(FXH-DXHZ)}	Disable time, DX high impedance following last data bit from FSX high			P + 4	3P + 17	ns		
8	t _{d(FXL-DXV)}	Delay time, FSX low to DX valid			2P + 1	4P + 13	ns		

 $^{^{\}dagger}$ P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns.

[‡] For all SPI slave modes, CLKG is programmed as 1/2 of the CPU clock by setting CLKSM = CLKGDV = 1.

[‡] For all SPI slave modes, CLKG is programmed as 1/2 of the CPU clock by setting CLKSM = CLKGDV = 1.

[§] S = sample rate generator input clock = P if CLKSM = 1 (P = 1/CPU clock frequency)

⁼ sample rate generator input clock = P clks if CLKSM = 0 (P clks = CLKS period)

T = CLKX period = (1 + CLKGDV) * S

H = CLKX high pulse width = (CLKGDV/2 + 1) * S if CLKGDV is even

^{= (}CLKGDV + 1)/2 * S if CLKGDV is odd or zero

L = CLKX low pulse width = (CLKGDV/2) * S if CLKGDV is even

^{= (}CLKGDV + 1)/2 * S if CLKGDV is odd or zero

FSRP = FSXP = 1. As a SPI master, FSX is inverted to provide active-low slave-enable output. As a slave, the active-low signal input on FSX and FSR is inverted before being used internally.

CLKXM = FSXM = 1, CLKRM = FSRM = 0 for master McBSP

CLKXM = CLKRM = FSXM = FSRM = 0 for slave McBSP

[#] FSX should be low before the rising edge of clock to enable slave devices and then begin a SPI transfer at the rising edge of the master clock (CLKX).

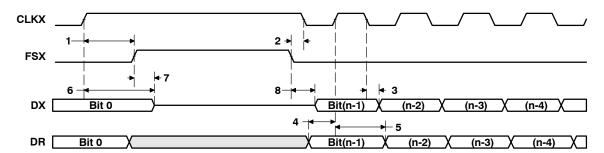


Figure 37. McBSP Timing as SPI Master or Slave: CLKSTP = 10b, CLKXP = 1

timing requirements for McBSP as SPI master or slave: CLKSTP = 11b, CLKXP = 1^{†‡} (see Figure 38)

NO.			C6701-120 C6701-150 C6701-167			UNIT	
		MASTER		SLAVE			
			MIN	MAX	MIN	MAX	
4	t _{su(DRV-CKXL)} Setup	ime, DR valid before CLKX low	12		2 – 3P		ns
5	t _{h(CKXL-DRV)} Hold ti	ne, DR valid after CLKX low	4		5 + 6P		ns

 $^{^{\}dagger}$ P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns.

switching characteristics for McBSP as SPI master or slave: CLKSTP = 11b, CLKXP = $1^{\dagger \ddagger}$ (see Figure 38)

NO.		PARAMETER		UNIT			
		MASTER§			SLAVE		
			MIN	MAX	MIN	MAX	
1	t _{h(CKXH-FXL)}	Hold time, FSX low after CLKX high [¶]	H – 4	H + 4			ns
2	t _{d(FXL-CKXL)}	Delay time, FSX low to CLKX low#	T – 4	T + 4			ns
3	t _{d(CKXH-DXV)}	Delay time, CLKX high to DX valid	-4	4	3P + 1	5P + 17	ns
6	t _{dis(CKXH-DXHZ)}	Disable time, DX high impedance following last data bit from CLKX high	-2	4	3P + 4	5P + 17	ns
7	t _{d(FXL-DXV)}	Delay time, FSX low to DX valid	L – 2	L + 3	2P + 1	4P + 13	ns

 $^{^{\}dagger}$ P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns.

= (CLKGDV + 1)/2 * S if CLKGDV is odd or zero

L = CLKX low pulse width = (CLKGDV/2) * S if CLKGDV is even

= (CLKGDV + 1)/2 * S if CLKGDV is odd or zero

CLKXM = FSXM = 1, CLKRM = FSRM = 0 for master McBSP

CLKXM = CLKRM = FSXM = FSRM = 0 for slave McBSP



[‡] For all SPI slave modes, CLKG is programmed as 1/2 of the CPU clock by setting CLKSM = CLKGDV = 1.

[‡] For all SPI slave modes, CLKG is programmed as 1/2 of the CPU clock by setting CLKSM = CLKGDV = 1.

[§] S = sample rate generator input clock = P if CLKSM = 1 (P = 1/CPU clock frequency)

⁼ sample rate generator input clock = P_clks if CLKSM = 0 (P_clks = CLKS period)

T = CLKX period = (1 + CLKGDV) * S

H = CLKX high pulse width = (CLKGDV/2 + 1) * S if CLKGDV is even

FSRP = FSXP = 1. As a SPI master, FSX is inverted to provide active-low slave-enable output. As a slave, the active-low signal input on FSX and FSR is inverted before being used internally.

[#] FSX should be low before the rising edge of clock to enable slave devices and then begin a SPI transfer at the rising edge of the master clock (CLKX).

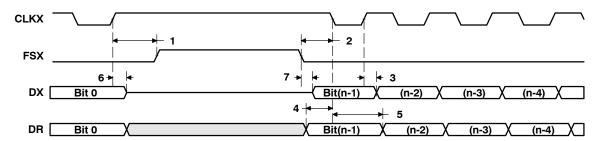
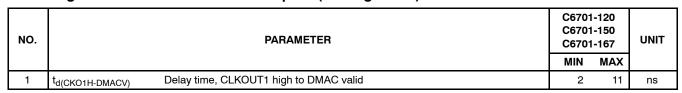


Figure 38. McBSP Timing as SPI Master or Slave: CLKSTP = 11b, CLKXP = 1

DMAC, TIMER, POWER-DOWN TIMING

switching characteristics for DMAC outputs (see Figure 39)



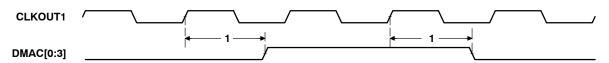


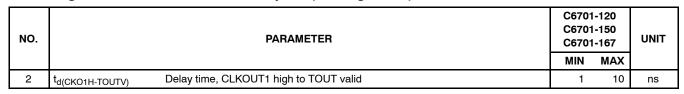
Figure 39. DMAC Timing

timing requirements for timer inputs (see Figure 40)†

NO.		C6701 C6701 C6701	UNIT	
		MIN	MAX	
1	t _{w(TINPH)} Pulse duration, TINP high	2P		ns

 $^{^{\}dagger}$ P = 1/CPU clock frequency in ns. For example, when running parts at 167 MHz, use P = 6 ns.

switching characteristics for timer outputs (see Figure 40)



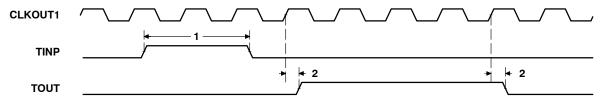
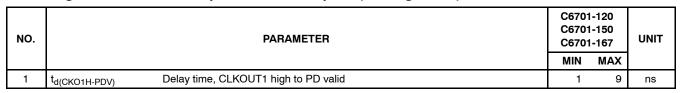


Figure 40. Timer Timing

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DMAC, TIMER, POWER-DOWN TIMING (CONTINUED)

switching characteristics for power-down outputs (see Figure 41)



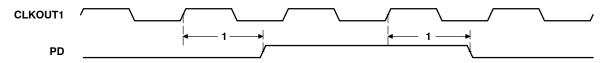


Figure 41. Power-Down Timing

JTAG TEST-PORT TIMING

timing requirements for JTAG test port (see Figure 42)

NO.			C6701 C6701 C6701	-150	UNIT
			MIN	MAX	
1	t _{c(TCK)}	Cycle time, TCK	35		ns
3	t _{su(TDIV-TCKH)}	Setup time, TDI/TMS/TRST valid before TCK high	10		ns
4	t _{h(TCKH-TDIV)}	Hold time, TDI/TMS/TRST valid after TCK high	9		ns

switching characteristics for JTAG test port (see Figure 42)

NO.	PARAMETER			UNIT
		MIN	MAX	
2	t _{d(TCKL-TDOV)} Delay time, TCK low to TDO valid	-3	12	ns

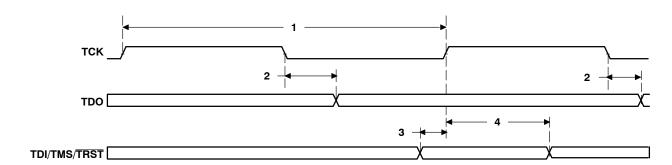
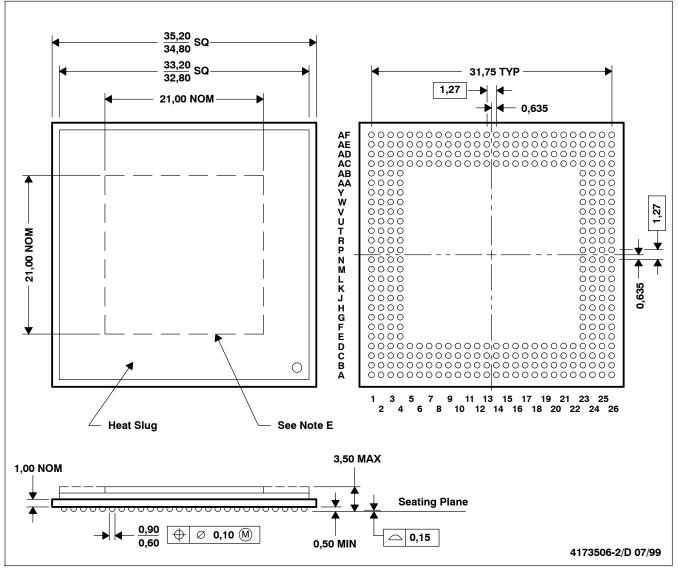


Figure 42. JTAG Test-Port Timing

MECHANICAL DATA

GJC (S-PBGA-N352)

PLASTIC BALL GRID ARRAY



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Thermally enhanced plastic package with heat slug (HSL).
 - D. Flip chip application only
 - E. Possible protrusion in this area, but within 3,50 max package height specification
 - F. Falls within JEDEC MO-151/BAR-2

thermal resistance characteristics (S-PBGA package)

NO		°C/W	Air Flow LFPM [†]
1	RΘ _{JC} Junction-to-case	0.74	N/A
2	RΘ _{JA} Junction-to-free air	11.31	0
3	RΘ _{JA} Junction-to-free air	9.60	100
4	RΘ _{JA} Junction-to-free air	8.34	250
5	RΘ _{JA} Junction-to-free air	7.30	500

[†] LFPM = Linear Feet Per Minute



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REVISION HISTORY

This data sheet revision history highlights the technical changes made to the SPR067E device-specific data sheet to make it an SPRS067F revision.

Scope: Applicable updates to the C67x device family, specifically relating to the C6701 device, have been incorporated.

PAGE(S) NO.	ADDITIONS/CHANGES/DELETIONS						
All	Updated the title for literature number SPRU190 to: TMS320C6000 DSP Peripherals Overview Reference Guide						
26	Added the power-down mode logic section and accompanying information.						





.com 31-Aug-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TMS320C6701GJC150	ACTIVE	FC/CSP	GJC	352	24	TBD	SN/PB	Level-4-220C-72HR
TMS320C6701GJC167	OBSOLETE	FC/CSP	GJC	352		TBD	Call TI	Call TI
TMS320C6701GJCA120	ACTIVE	FC/CSP	GJC	352	24	TBD	SN/PB	Level-4-220C-72HR
TMSC6701GJC16719V	ACTIVE	FC/CSP	GJC	352	24	TBD	SN/PB	Level-4-220C-72HR
TMX320C6701GJC	OBSOLETE	FC/CSP	GJC	352		TBD	Call TI	Call TI

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

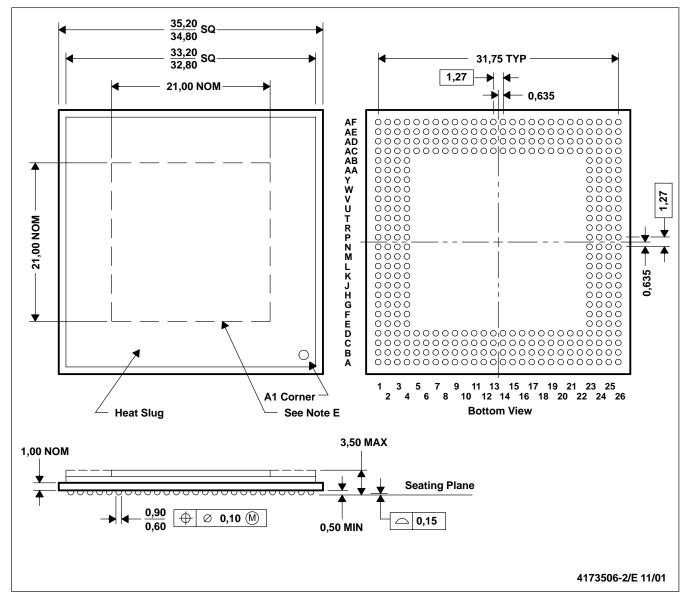
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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GJC (S-PBGA-N352)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Thermally enhanced plastic package with heat slug (HSL).
- D. Flip chip application only
- E. Possible protrusion in this area, but within 3,50 max package height specification
- F. Falls within JEDEC MO-151/BAR-2

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Наши контакты:

Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург,

Промышленная ул, дом № 19, литера Н,

помещение 100-Н Офис 331